

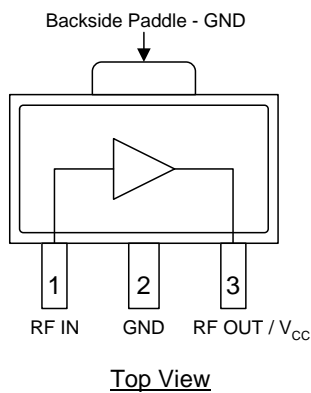
### General Description

The TQP7M9101 is a high-linearity driver amplifier in a standard SOT-89 surface mount package. This InGaP/GaAs HBT delivers high performance across a broad range of frequencies with +40 dBm OIP3 and with +25 dBm P1dB while only consuming 87 mA quiescent current. All devices are 100% RF and DC tested.

The TQP7M9101 incorporates on-chip features that differentiate it from other products in the market. The RF output is internally matched in to 50 ohms. Only input matching is required for optimal performance in specific frequency bands making the component easy for design engineers to implement in their systems. The amplifier integrates an on-chip DC over-voltage and RF over-drive protection. This protects the amplifier from electrical DC voltage surges and high input RF input power levels that may occur in a system. On-chip ESD protection allows the amplifier to have a very robust Class 1C HBM ESD rating.

The TQP7M9101 is targeted for use as a driver amplifier in wireless infrastructure where high linearity, medium power, and high efficiency are required. The device an excellent candidate for transceiver line cards in current and next generation multi-carrier 3G / 4G base stations.

### Functional Block Diagram



3 Pin SOT-89 Package

### Product Features

- 400 – 5000 MHz
- +25 dBm P1dB
- +39.5 dBm Output IP3
- 17.5 dB Gain at 2140 MHz
- +5 V Single Supply, 87 mA Current
- No Output Matching Required
- Internal RF Overdrive Protection
- Internal DC Overvoltage Protection
- On-Chip ESD Protection
- SOT-89 Package

### Applications

- Repeaters
- Mobile Infrastructure
- CDMA / WCDMA / LTE
- General Purpose Wireless

### Ordering Information

Part No.	Description
TQP7M9101	1/4 W High Linearity Amplifier
TQP7M9101-PCB900	869 – 960 MHz Evaluation Board
TQP7M9101-PCB2140	2.11 – 2.17 GHz Evaluation Board
TQP7M9101-PCB2600	2.5 – 2.7 GHz Evaluation Board

Standard T/R size = 1000 pieces on a 7" reel

## Absolute Maximum Ratings

Parameter	Rating
Storage Temperature	-65 to 150 °C
RF Input Power, CW, 50Ω, T=25°C	+23 dBm
Device Voltage (V <sub>CC</sub> )	+8 V

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability.

## Recommended Operating Conditions

Parameter	Min	Typ	Max	Units
Device Voltage (V <sub>CC</sub> )	+3	+5	+5.25	V
T <sub>CASE</sub>	-40		+105	°C
T <sub>j</sub> for >10 <sup>6</sup> hours MTTF			+170	°C

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions.

## Electrical Specifications

Parameter	Conditions <sup>(1)</sup>	Min	Typ	Max	Units
Operational Frequency Range		400		5000	MHz
Test Frequency			2140		MHz
Gain		15.6	17.5	18.6	dB
Input Return Loss			15		dB
Output Return Loss			13.5		dB
Output P1dB		+23.5	+25		dBm
Output IP3	P <sub>out</sub> = +8 dBm/tone, Δf = 1 MHz	+36.5	+39.5		dBm
WCDMA Channel Power	-50 dBc ACLR, Note 2		+14.5		dBm
Noise Figure			3.9		dB
Quiescent Current, I <sub>CC</sub>		70	87	105	mA
Thermal Resistance, θ <sub>Jc</sub>	Junction to case			71	°C/W

Notes:

1. Test conditions unless otherwise noted: V<sub>CC</sub> = +5 V, Temp. = +25 °C, matched 2140 MHz reference circuit
2. ACLR test set-up: 3GPP WCDMA, TM1+64 DPCH, +5 MHz offset, PAR = 10.2 dB at 0.01% Probability

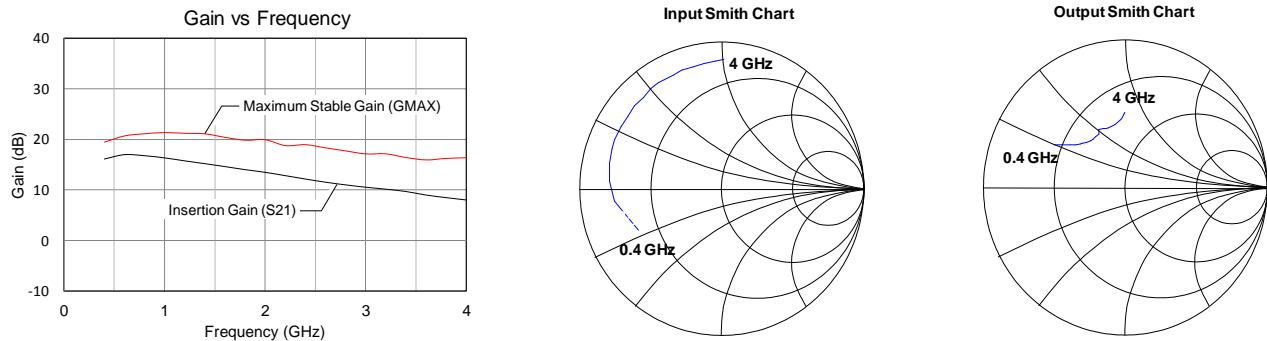
## Performance Summary Table

Frequency	635	700	800	960	1500	1805	1900	2100	2140	2600	3500	MHz
Gain	20	18.5	18.7	20.1	19.4	18.0	16.6	15.9	17.5	16.5	15.0	dB
Input Return Loss	12	11.8	17.7	14	19	10.7	12	12	15	10	17	dB
Output Return Loss	33	12.8	19.1	17	13	15.8	11	9.5	13.5	14	11	dB
Output P1dB	+25.0	+24.1	+24.2	+24.4	+23.8	+25.0	+24.0	+24.2	+24.8	+24.9	+23.4	dBm
Output IP3	+40.0	+39.6	+40.4	+38.2	+42.8	+39.7	+47.8	+43.8	+39.5	+40.6	+39.4	dBm

Notes:

1. Test conditions unless otherwise noted: V<sub>CC</sub> = +5 V, Temp. = +25 °C, matched reference circuit
2. Reference designs for the various frequencies are either included on this datasheet or may be obtained by contacting [appsupport@qorvo.com](mailto:appsupport@qorvo.com)

Device Characterization Data



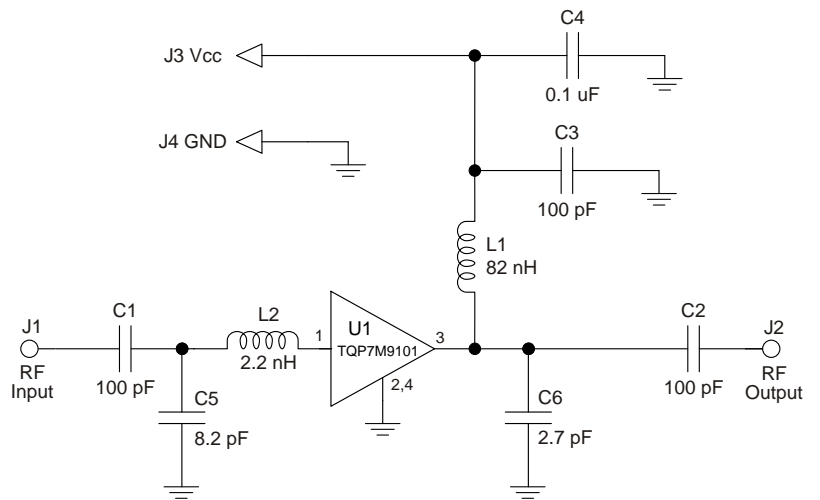
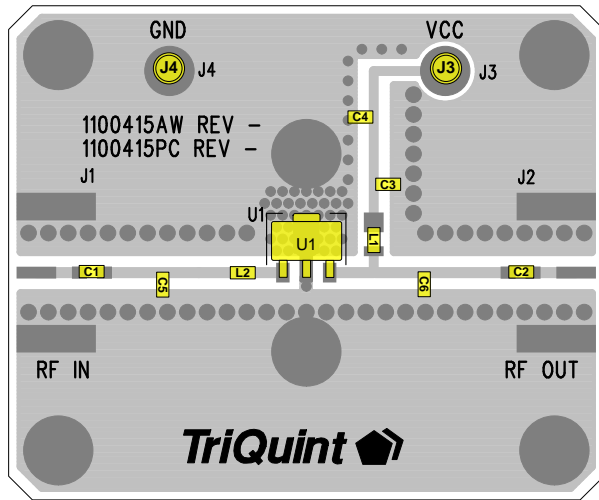
Note: The gain for the unmatched device in a 50 ohm system is shown as the black trace labeled "Gain (S21)". In a circuit tuned for a particular frequency, it is expected that actual gain will be higher, up to the maximum stable gain. The maximum stable gain is shown as the red trace [Gmax]. The impedance Smith chart plots are shown from 0.05 to 4 GHz.

S-Parameters

Freq (MHz)	S11 (dB)	S11 (ang)	S21 (dB)	S21 (ang)	S12 (dB)	S12 (ang)	S22 (dB)	S22 (ang)
400	-3.74	-154.94	16.08	172.65	-30.84	32.65	-4.47	155.03
600	-2.43	-174.00	16.93	152.42	-28.85	13.25	-6.02	149.89
800	-2.00	175.84	16.72	137.72	-28.64	3.42	-6.63	147.55
1000	-1.81	167.43	16.29	123.90	-28.38	-4.74	-7.05	144.48
1200	-1.71	160.50	15.71	112.48	-28.45	-10.23	-7.29	142.81
1400	-1.68	155.82	15.15	102.29	-28.29	-15.72	-7.67	139.67
1600	-1.66	149.16	14.58	91.96	-28.34	-19.66	-7.92	136.04
1800	-1.65	143.36	13.98	82.32	-28.40	-25.64	-8.05	132.86
2000	-1.56	137.28	13.45	72.43	-28.25	-30.76	-8.05	129.68
2200	-1.60	131.41	12.80	64.37	-28.52	-35.06	-7.96	125.67
2400	-1.43	126.29	12.14	56.45	-28.43	-39.47	-7.47	122.90
2600	-1.41	122.01	11.52	48.81	-28.73	-42.87	-7.49	122.21
2800	-1.43	117.57	10.99	41.39	-28.68	-47.17	-7.71	119.34
3000	-1.45	114.12	10.53	34.73	-28.78	-49.96	-7.92	116.57
3200	-1.36	109.38	10.15	27.42	-28.85	-52.90	-7.87	114.37
3400	-1.40	103.72	9.69	19.90	-29.00	-59.40	-7.85	106.77
3600	-1.32	98.51	8.99	12.40	-29.04	-63.10	-7.32	100.14
3800	-1.19	93.06	8.49	5.24	-29.04	-68.03	-6.75	96.77
4000	-1.11	89.37	8.02	-0.57	-29.02	-70.86	-6.53	95.94

Test Conditions: V<sub>CC</sub> = +5 V, I<sub>CC</sub> = 87 mA, Temp. = +25 °C, unmatched 50 Ohm system, reference plane at device leads

## 617 – 652 MHz Reference Design



**Notes:**

1. See Evaluation Board PCB Information section for PCB material and stack-up
2. All components are 0603 size unless otherwise specified.
3. Critical component placement locations:  
 Distance from U1 Pin 1 (left edge) to L2 (right edge): 90 mils  
 Distance from U1 Pin 1 (left edge) to C5 (right edge): 310 mils  
 Distance from U1 Pin 3 (right edge) to C6 (left edge): 245 mils

## Bill of Material 617 – 652 MHz Reference Design

Reference Des.	Value	Description	Manuf.	Part Number
n/a	n/a	Printed Circuit Board	Qorvo	1100415
U1	n/a	Amplifier, SOT-89 pkg.	Qorvo	TQP7M9101
L1	82 nH	Inductor, 0805, 5%, Coilcraft CS Series	Coilcraft	0805CS-820XJLB
L2	2.2 nH	Inductor, Chip, 0603	various	
C1, C2, C3	100 pF	Cap., Chip, 5%, 50 V, NPO/COG	various	
C4	0.1 uF	Cap., Chip, 10%, 50 V, X7R	various	
C5	8.2 pF	Cap., Chip, +/-0.1 pF. 50 V NPO/COG	various	
C6	2.7 pF	Cap., Chip, +/-0.1 pF. 50 V NPO/COG	various	
J3, J4	n/a	Solder Turret	various	

## Typical Performance 617 – 652 MHz Reference Design

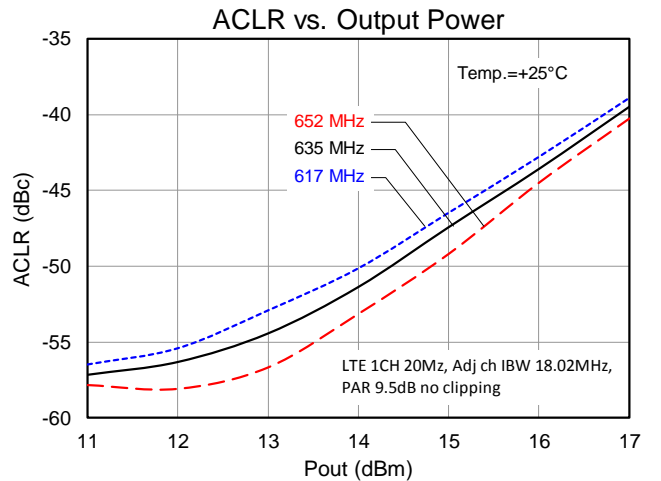
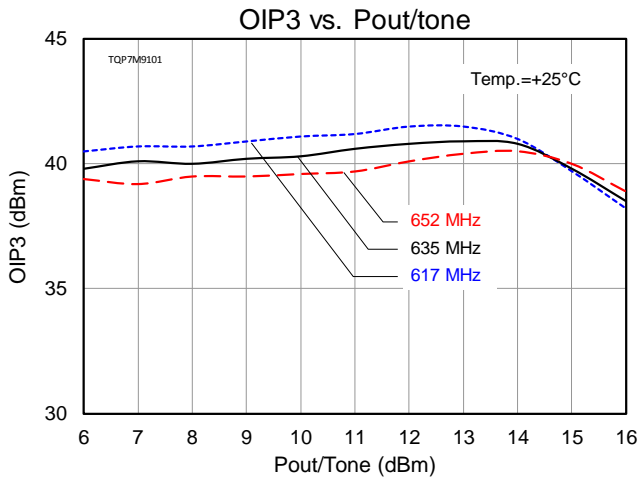
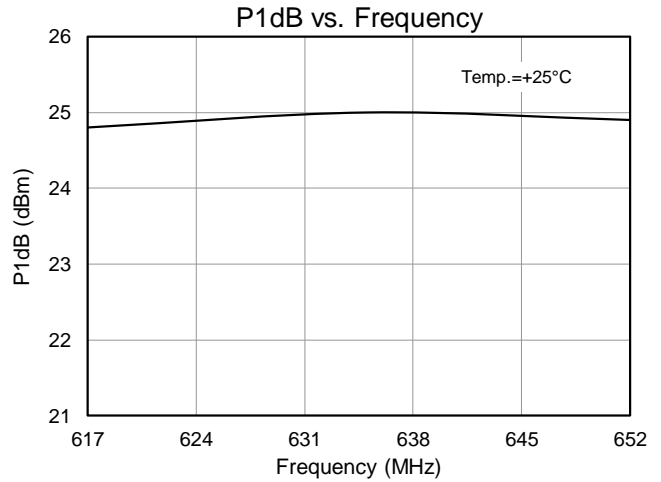
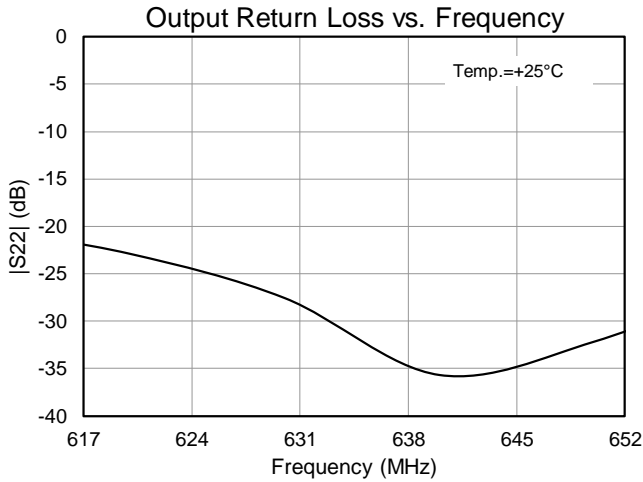
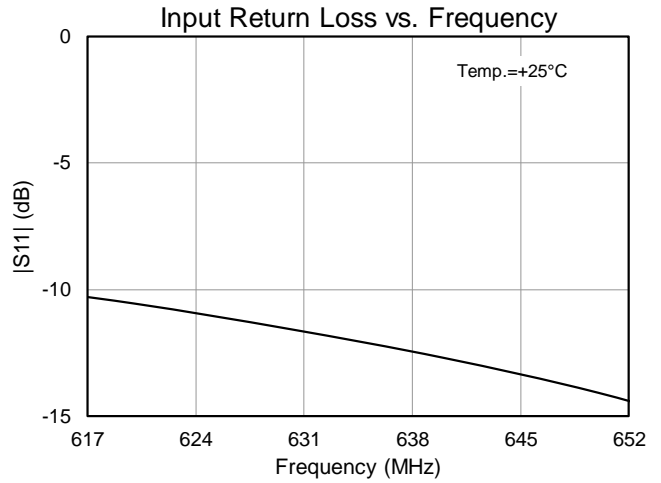
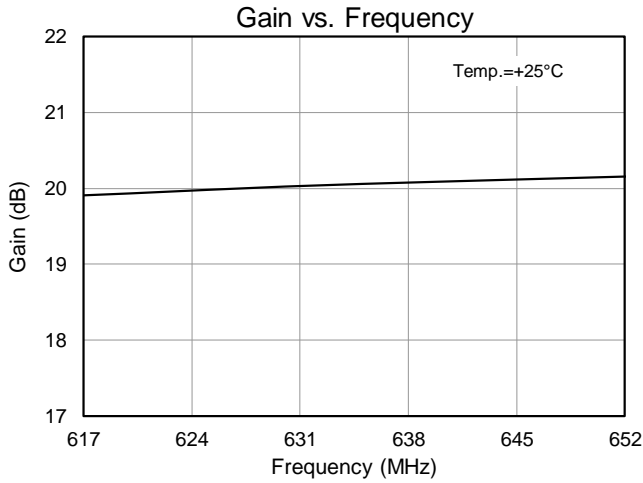
Parameter		Typical Value			
		617	635	652	MHz
Frequency (MHz)		617	635	652	MHz
Gain		20	20	20	dB
Input Return Loss		10	12	14	dB
Output Return Loss		22	33	31	dB
Output P1dB		+24.8	+25.0	+24.9	dBm
Output IP3	P <sub>out</sub> =+8 dBm/tone, Δf = 1 MHz	+40.7	+40.0	+39.5	dBm
LTE Chan. Power <sup>(2)</sup>	-50 dBc ACLR	+14.0	+14.4	+14.8	dBm

**Notes:**

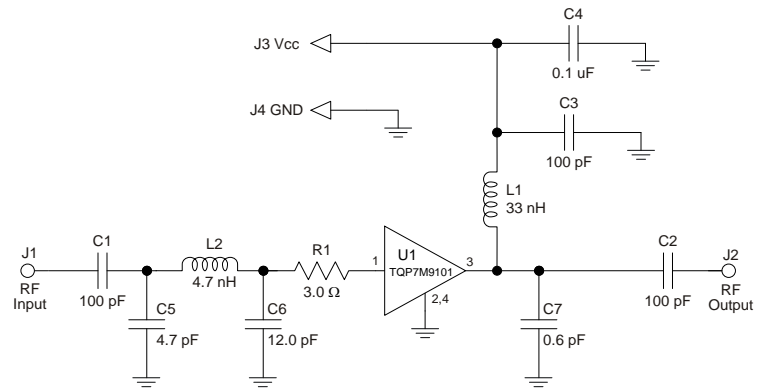
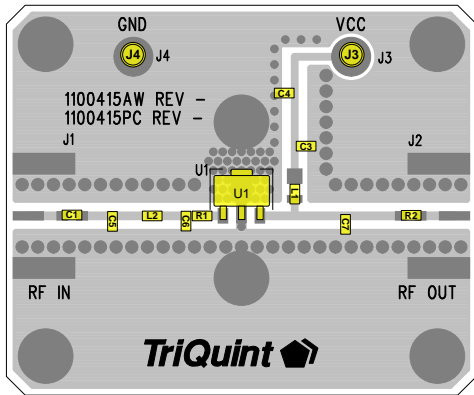
1. Test conditions unless otherwise noted: VCC = +5 V, ICQ = 87 mA (typ.), Temp. = +25 °C
2. ACLR test set-up: 1 CH, 20 MHz BW, LTE E-TM1.1, 9.5 dB PAR at 0.01% Probability

**Performance Plots 617 – 652 MHz Reference Design**

Test conditions unless otherwise noted:  $V_{CC} = +5\text{ V}$ ,  $I_{CQ} = 87\text{ mA}$  (typ.), Temp. =  $+25^\circ\text{C}$



## 700 – 1000 MHz Reference Design



- Notes:
1. See Evaluation Board PCB Information section for PCB material and stack-up
  2. All components are 0603 size unless otherwise specified.
  3. Critical component placement locations:
    - Distance from U1 Pin 1 Pad (left edge) to R1 (right edge): 10 mils (0.5° at 900 MHz)
    - Distance from R1 (left edge) to C6 (right edge): 5 mils (0.2° at 900 MHz)
    - Distance from C6 (left edge) to L2 (right edge): 60 mils (2.8° at 900 MHz)
    - Distance from L2 (left edge) to C5 (right edge): 60 mils (2.8° at 900 MHz)
    - Distance from U1 Pin 3 Pad (right edge) to C7 (left edge): 250 mils (11.7° at 900 MHz)

## Bill of Material 700 – 1000 MHz Reference Design

Reference Des.	Value	Description	Manuf.	Part Number
n/a	n/a	Printed Circuit Board	Qorvo	1100415
U1	n/a	Amplifier, SOT-89 pkg.	Qorvo	TQP7M9101
L1	33 nH	Inductor, 0805, 5%, Coilcraft CS Series	Coilcraft	0805CS-330XJLB
L2	4.7 nH	Inductor, Chip, 0603	various	
C1, C2, C3	100 pF	Cap., Chip, 5%, 50 V, NPO/COG	various	
C4	0.1 uF	Cap., Chip, 10%, 50 V, X7R	various	
C5	4.7 pF	Cap., Chip, +/-0.1 pF. 50 V NPO/COG	various	
C6	12 pF	Cap., Chip, 2% 50 V NPO/COG	various	
C7	0.6 pF	Cap., Chip, +/-0.05 pF. 50 V NPO/COG	various	
J3, J4	n/a	Solder Turret	various	

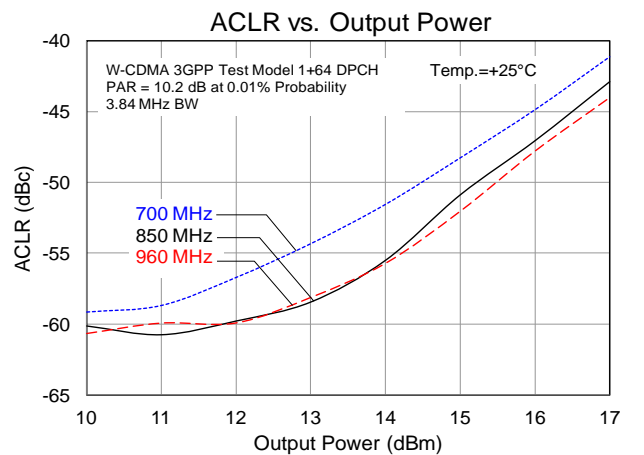
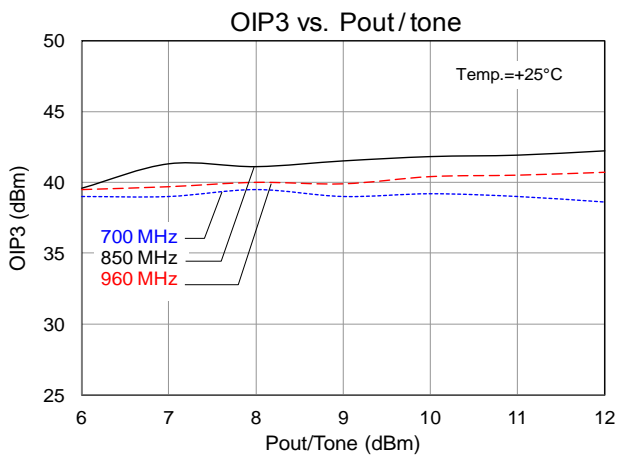
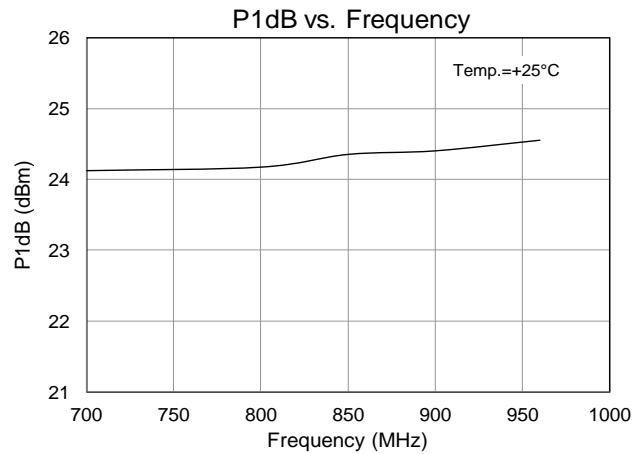
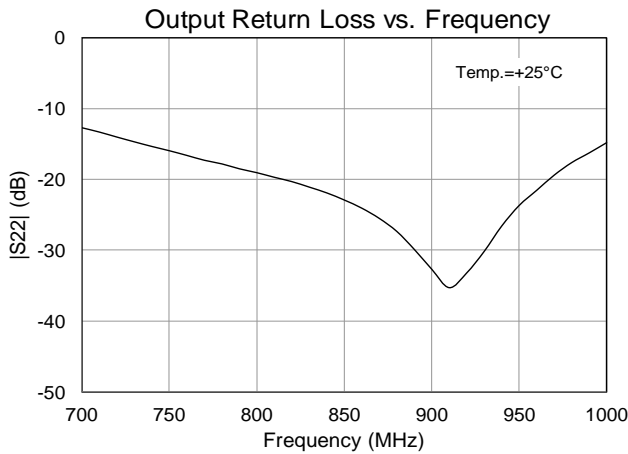
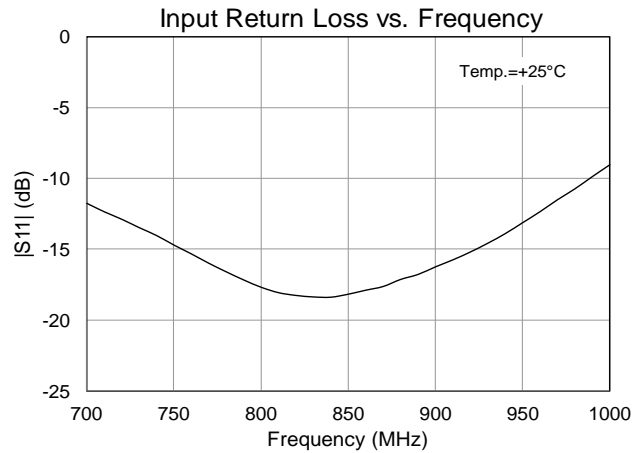
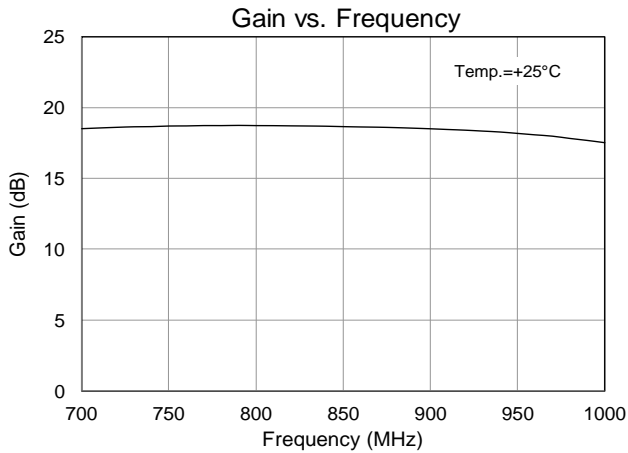
## Typical Performance 700 – 1000 MHz Reference Design

Parameter	Typical Value							
	700	800	850	900	960	MHz		
Frequency (MHz)								
Gain	18.5	18.7	18.6	18.5	18.2		dB	
Input Return Loss	11.8	17.7	18.2	16.2	13.1		dB	
Output Return Loss	12.8	19.1	22.9	32.7	23.7		dB	
Output P1dB	+24.1	+24.2	+24.4	+24.4	+24.6		dBm	
Output IP3	Pout=+8 dBm/tone, Δf = 1 MHz		+39.6	+40.4	+41.2	+39.7	+39.8	dBm
WCDMA Chan. Power <sup>(1)</sup>	-55 dBc ACLR		+12.8	+13.2	+13.5	+14.0	+14.0	dBm
Noise Figure	5.0	5.0	5.1	5.2	5.9		dB	

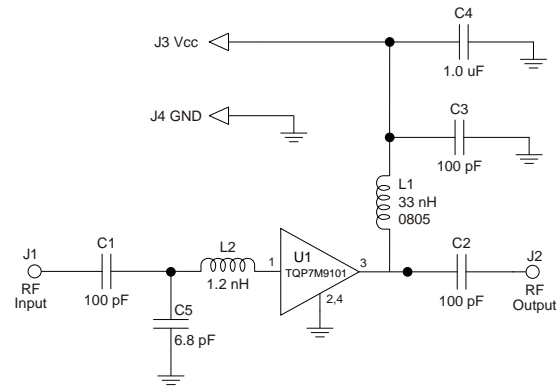
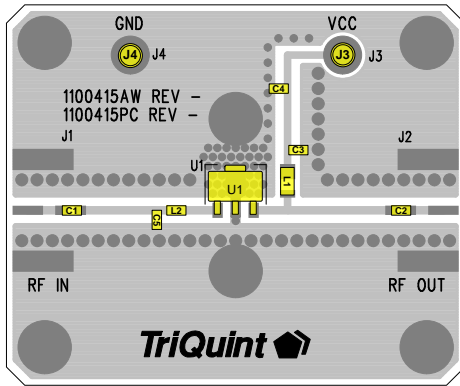
- Notes:
1. Test conditions unless otherwise noted: VCC = +5 V, ICQ = 87 mA (typ.), Temp. = +25 °C
  2. ACLR test set-up: 3GPP WCDMA, TM1+64 DPCH, +5 MHz offset, PAR = 10.2 dB at 0.01% Probability

**Performance Plots 700 – 1000 MHz Reference Design**

Test conditions unless otherwise noted:  $V_{CC} = +5\text{ V}$ ,  $I_{CQ} = 87\text{ mA}$  (typ.),  $Temp. = +25\text{ }^{\circ}\text{C}$



## 869 – 960 MHz Evaluation Board (TQP7M9101– PCB900)



**Notes:**

1. See Evaluation Board PCB Information section for PCB material and stack-up
2. Components (C1 and C2) are blocking capacitors and their locations are not critical to the matching network.
3. All components are of 0603 size unless otherwise specified.
4. Critical component placement locations:  
 Distance from U1 Pin 1 Pad (left edge) to L2 (right edge): 90 mils (4.8° at 920 MHz)  
 Distance from L2 (left edge) to C5 (right edge): 40 mils (2.1° at 920 MHz)

## Bill of Material TQP7M9101– PCB900

Reference Des.	Value	Description	Manuf.	Part Number
n/a	n/a	Printed Circuit Board	Qorvo	1100415
U1	n/a	Amplifier, SOT-89 pkg.	Qorvo	TQP7M9101
L1	33 nH	Inductor, 0805, 5%, Coilcraft CS Series	Coilcraft	0805CS-330XJLB
L2	1.2 nH	Inductor, Chip, 0603	various	
C1, C2, C3	100 pF	Cap., Chip, 5%, 50V, NPO/COG	various	
C4	1.0 uF	Cap., Chip, 10%, 10V, X5R	various	
C5	6.8 pF	Cap., Chip, +/-0.1pF. 50V NPO/COG	various	
J1, J2	n/a	RF SMA Connector	Johnson Comp.	142-0701-851
J3, J4	n/a	Solder Turret	various	

## Typical Performance TQP7M9101– PCB900

Parameter	Conditions	Typical Value			Units
Frequency		869	920	960	MHz
Gain		20.2	20.4	20.1	dB
Input Return Loss		12	17	14	dB
Output Return Loss		18	23	17	dB
Output P1dB		+24.3	+24.4	+24.4	dBm
OIP3	Pout= +8 dBm/tone, Δf=1 MHz	+39.2	+38.6	+38.2	dBm
WCDMA Channel Power <sup>(1)</sup>	-55 dBc ACLR	+12.7	+13.4	+13.5	dBm
Noise Figure		4.0	4.0	3.9	dB

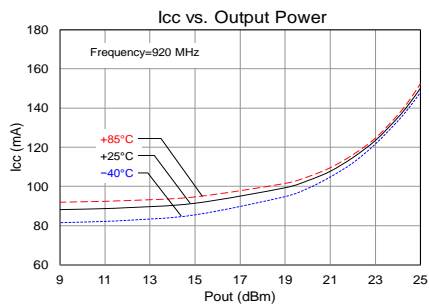
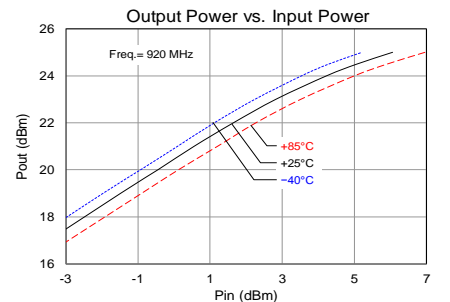
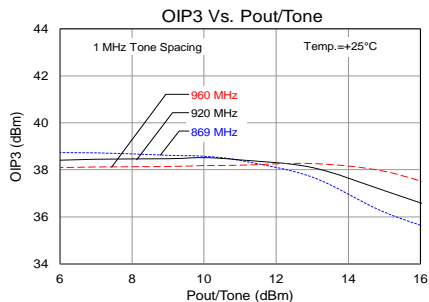
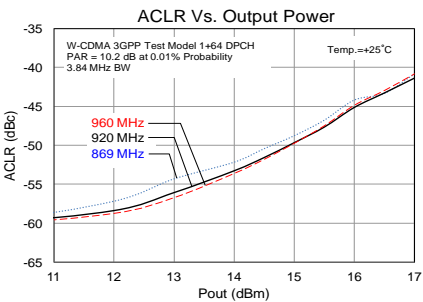
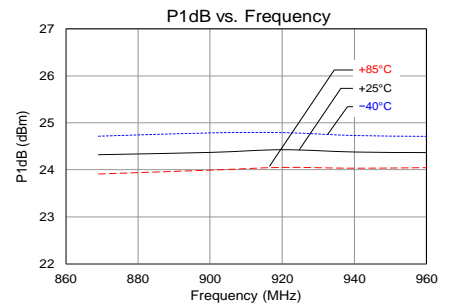
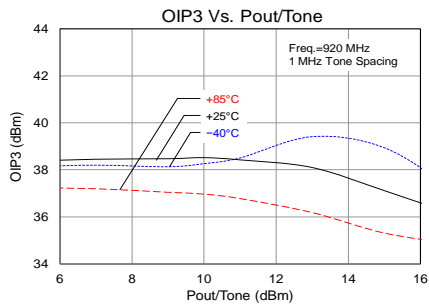
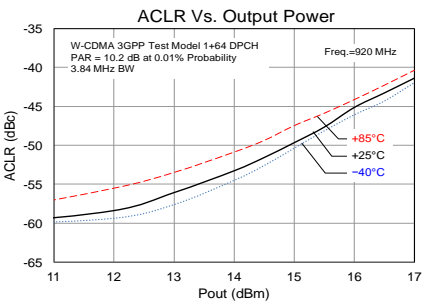
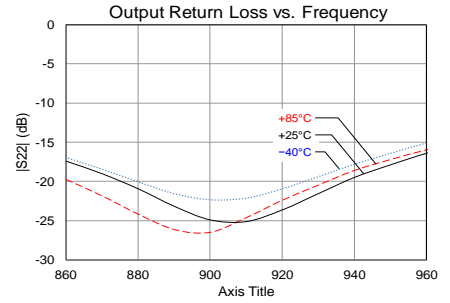
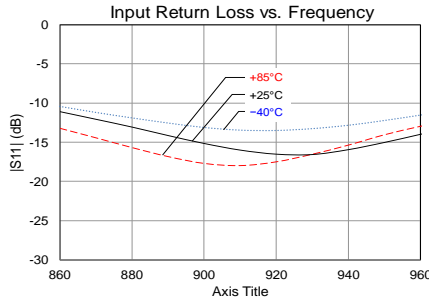
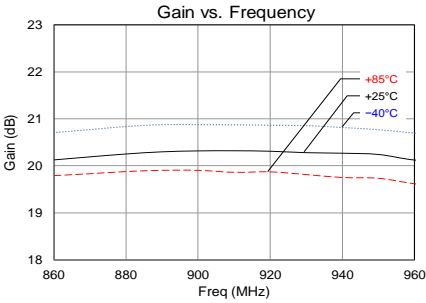
**Notes:**

1. Test conditions unless otherwise noted: V<sub>CC</sub> = +5 V, I<sub>CO</sub> = 87 mA (typ.), Temp. = +25 °C
2. ACLR Test set-up: 3GPP WCDMA, TM1+64 DPCH, +5 MHz offset, PAR = 10.2 dB at 0.01% Probability

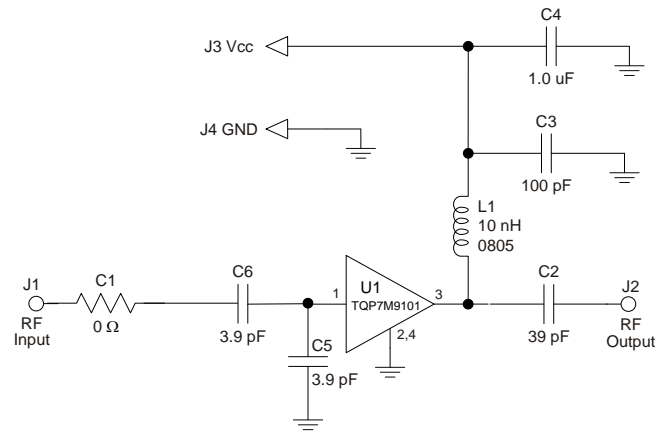
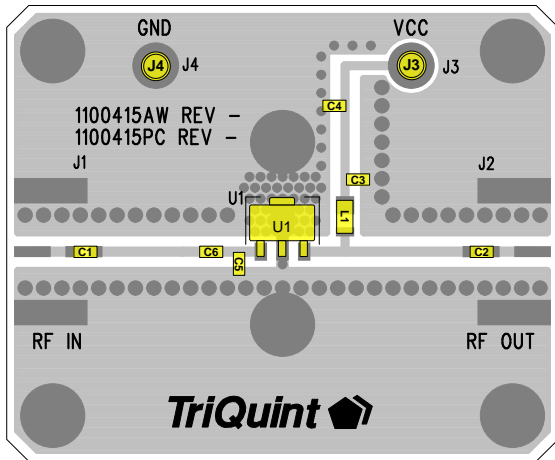


**Performance Plots TQP7M9101-PCB900**

Test conditions unless otherwise noted:  $V_{CC} = +5\text{ V}$ ,  $I_{CQ} = 87\text{ mA}$  (typ.), Temp. =  $+25\text{ }^{\circ}\text{C}$



## 1460 – 1540 MHz Reference Design



**Notes:**

1. See Evaluation Board PCB Information for material and stack up.
2. 0  $\Omega$  resistor (C1) may be replaced with copper trace in the target application layout.
3. All components are of 0603 size unless stated on the schematic.
4. Critical component placement locations:  
 Distance between U1 Pin 1 Pad (left edge) to C5 (right edge): 60 mils  
 Distance between U1 Pin 1 Pad (left edge) to C6 (right edge): 90 mils

## Bill of Material 1460 – 1540 MHz Reference Design

Reference Des.	Value	Description	Manuf.	Part Number
n/a	n/a	Printed Circuit Board	Qorvo	1100415
U1	n/a	0.25 W High Linearity Amplifier	Qorvo	TQP7M9101
C5 , C6	3.9 pF	CAP, 0603, +/-0.1pF. 200V. NPO/COG	various	
C1	0 $\Omega$	RES, 0603, +/-5%, 1/16 W	various	
C2	39 pF	CAP, 0603, +/-5%, 50V NPO/COG	various	
C3	100 pF	Cap., Chip, 0603, +/-5%. 50V NPO/COG	various	
C4	1.0 uF	CAP, 0603, 10%, X5R , 10V	various	
L1	10 nH	Inductor, 0805, 5%, Coilcraft CS Series	Coilcraft	0805CS-100XJLB
J3, J4	n/a	Solder Turret	various	

## Typical Performance 1460 – 1540 MHz Reference Design

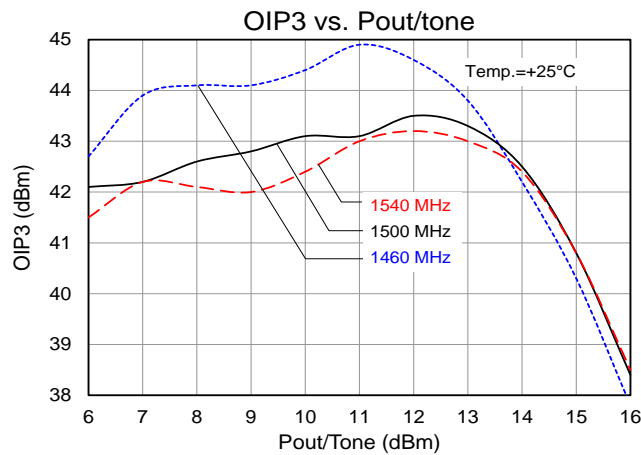
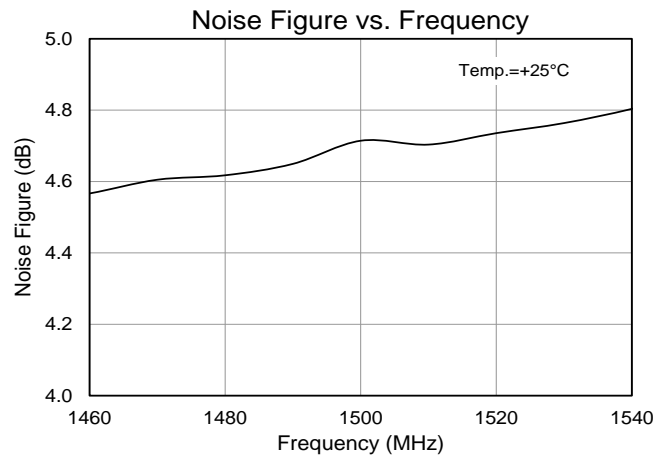
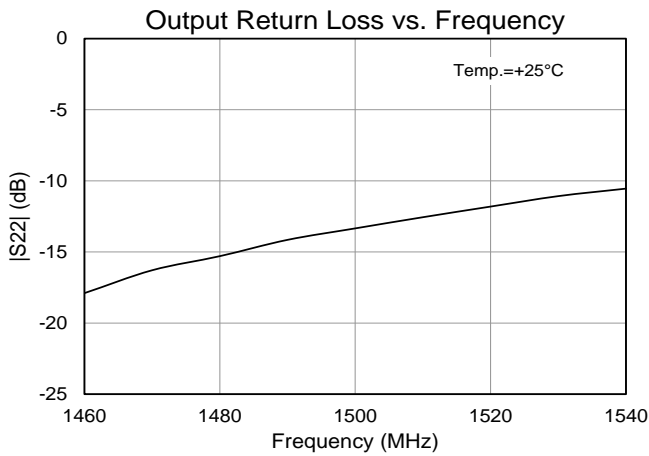
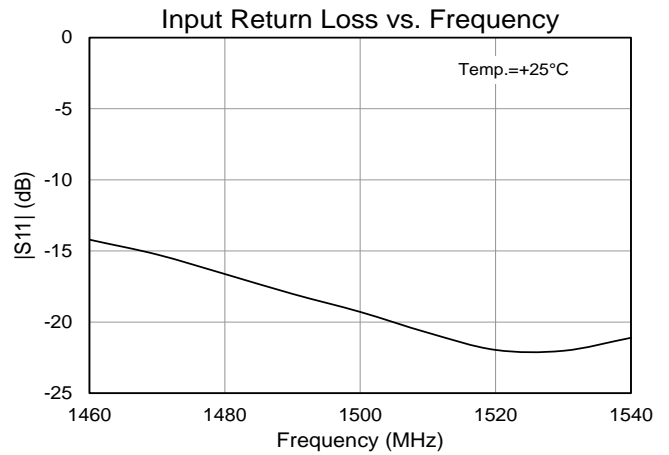
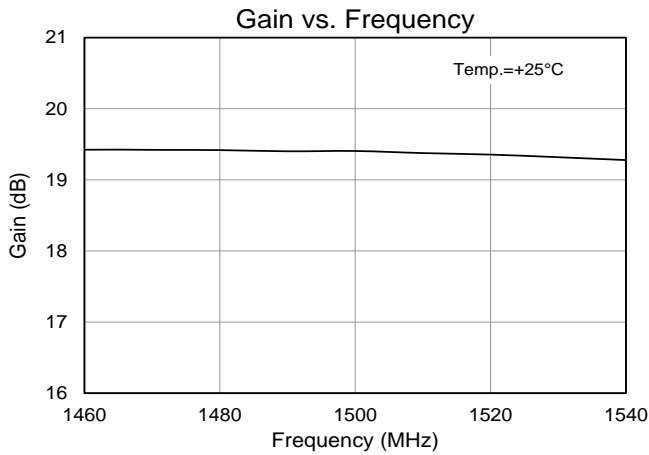
Parameter	Conditions	Typical Value			Units
		1460	1500	1540	
Frequency		1460	1500	1540	MHz
Gain		19.4	19.4	19.3	dB
Input Return Loss		14	19	20	dB
Output Return Loss		17	13	10	dB
Output P1dB		+24.4	+23.8	+23.7	dBm
OIP3	Pout= +8 dBm/tone, $\Delta f=1$ MHz	+44	+42.8	+42	dBm
Noise Figure		4.6	4.7	4.8	dBm

**Notes:**

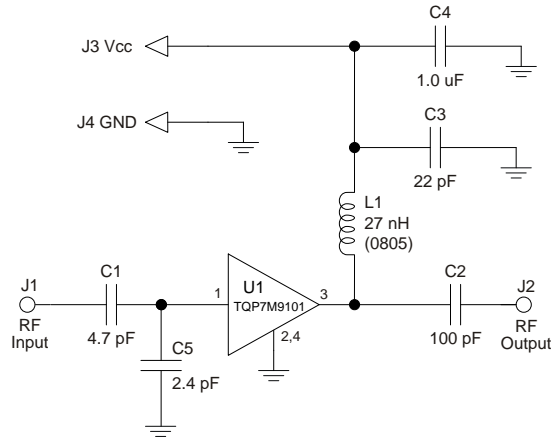
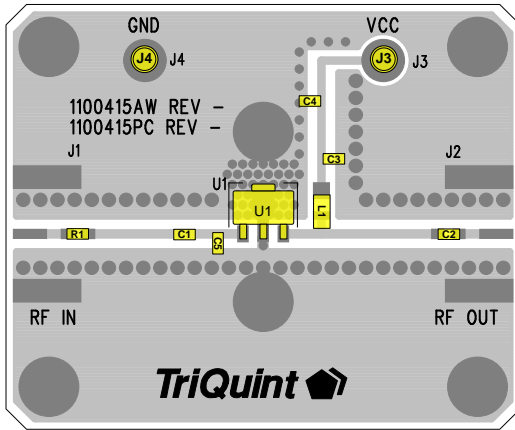
1. Test conditions unless otherwise noted:  $V_{CC} = +5$  V,  $I_{CQ} = 87$  mA (typ.), Temp. = +25  $^{\circ}$ C

Performance Plots 1460 – 1540 MHz Reference Design

Test conditions unless otherwise noted: VCC = +5 V, ICQ = 87 mA (typ.), Temp. = +25 °C



**1805 – 1990 MHz Reference Design**



**Notes:**

1. See Evaluation Board PCB Information section for PCB material and stack-up.
2. Component R1 on the PCB is a (0 Ω) Resistor and may be replaced by a copper trace
3. All components are of 0603 size unless otherwise specified.
4. Critical component placement:  
 Distance from U1 Pin 1 Pad (left edge) to C5 (right edge): 30 mils (3.0° at 1900 MHz)  
 Distance from C5 (left edge) to C1 (right edge): 55 mils (5.5° at 1900 MHz)

**Bill of Material 1805 – 1990 MHz Reference Design**

Reference Des.	Value	Description	Manuf.	Part Number
n/a	n/a	Printed Circuit Board	Qorvo	1100415
U1	n/a	0.25 W High Linearity Amplifier	Qorvo	TQP7M9101
R1	0 Ω	RES, 0603, 5PCT. 1/16W. CHIP	various	
C1	4.7 pF	CAP, Chip, +/-0.1pF. 50V NPO/COG	various	
C5	2.4 pF	CAP, Chip, +/-0.1pF. 50V NPO/COG	various	
C2	100 pF	CAP, 0603, 5%, 50V, NPO/COG	various	
C3	22 pF	CAP, 0603, 5%, 50V, NPO/COG	various	
C4	1.0 uF	CAP, 0603, 10%, X5R , 10V	various	
L1	27 nH	Inductor, 0805, 5%, Coilcraft CS series	Coilcraft	0805CS-270XJLB
J3, J4	n/a	Solder Turret	various	

**Typical Performance 1805 – 1990 MHz Reference Design**

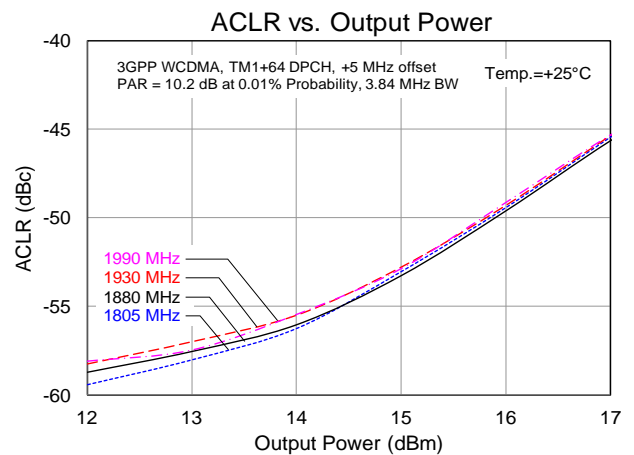
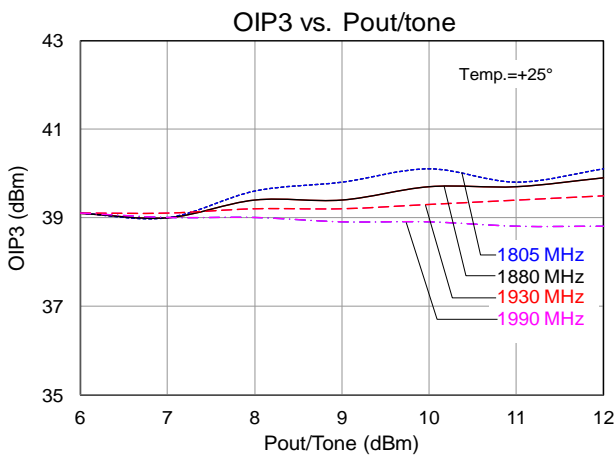
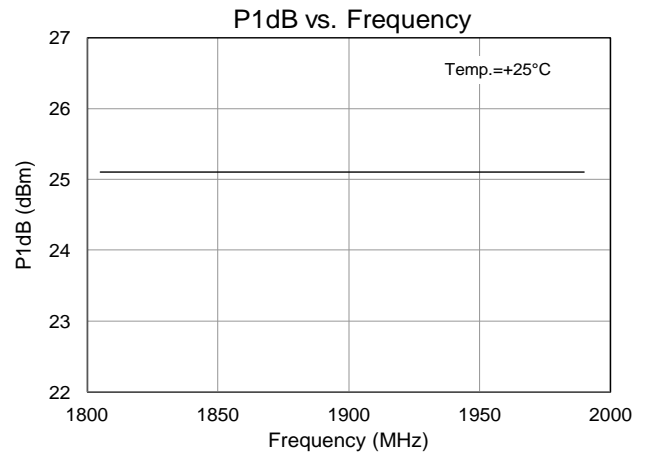
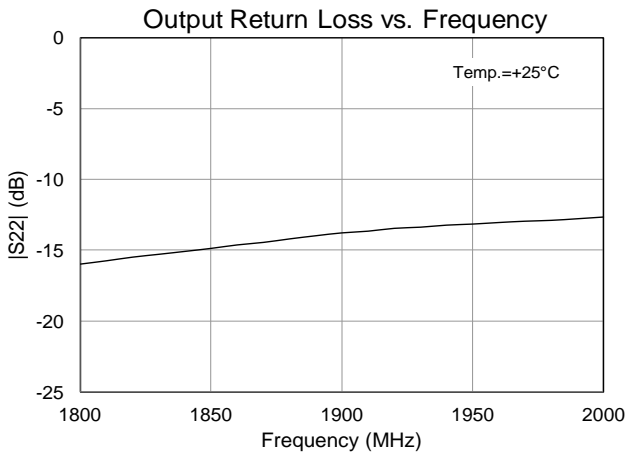
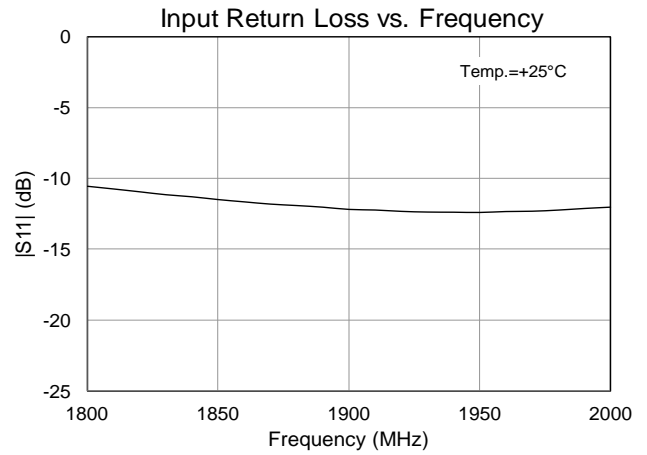
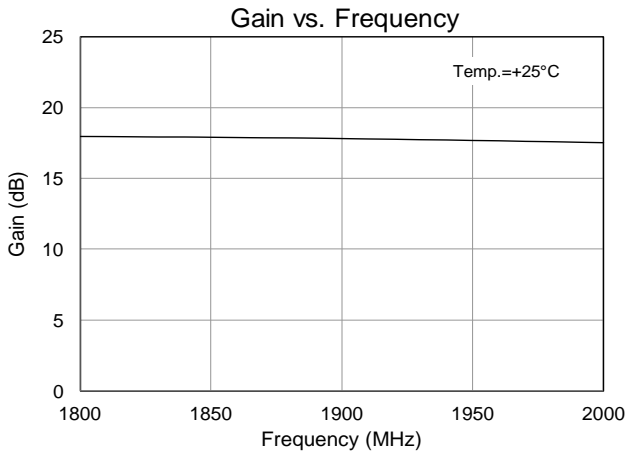
Parameter	Conditions <sup>(1)</sup>	Typical Value						Units
		1805	1850	1880	1930	1960	1990	
Frequency (MHz)		1805	1850	1880	1930	1960	1990	MHz
Gain		18.0	17.9	17.9	17.7	17.7	17.6	dB
Input Return Loss		10.7	11.5	11.9	12.4	12.4	12.2	dB
Output Return Loss		15.8	14.9	14.2	13.4	13.1	12.8	dB
Output P1dB		+25.0	+25.1	+25.1	+25.1	+25.1	+25.1	dBm
Output IP3	+8 dBm/tone, Δf = 1 MHz	+39.7	+39.6	+39.5	+39.2	+38.7	+39.1	dBm
WCDMA Channel Power	-55 dBc ACLR, Note 2	+14.5	+14.5	+14.4	+14.3	+14.0	+14.1	dBm

**Notes:**

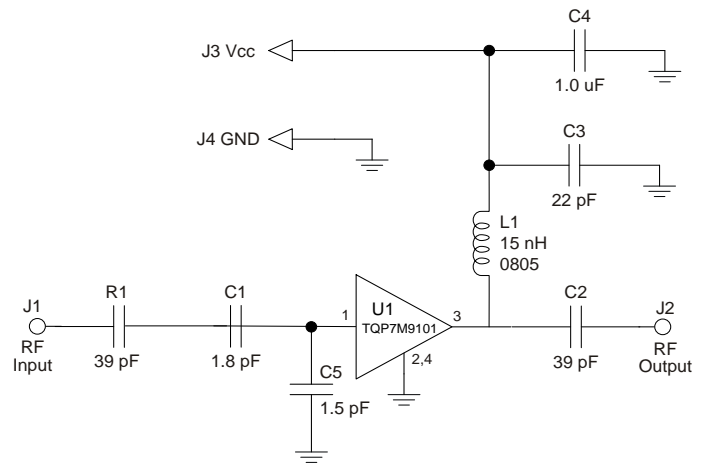
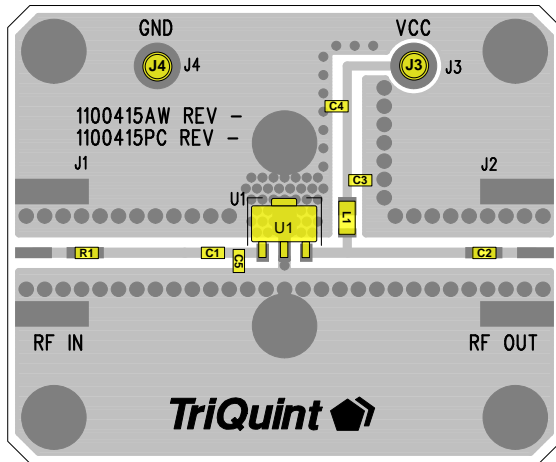
1. Test conditions unless otherwise noted: V<sub>CC</sub> = +5 V, I<sub>CO</sub> = 87 mA (typ.), Temp. = +25 °C
2. ACLR Test set-up: 3GPP WCDMA, TM1+64 DPCH, +5 MHz offset, PAR = 10.2 dB at 0.01% Probability

**Performance Plots 1805 – 1990 MHz**

Test conditions unless otherwise noted:  $V_{CC} = +5\text{ V}$ ,  $I_{CQ} = 87\text{ mA}$  (typ.), Temp. =  $+25^\circ\text{C}$



## 2110 – 2170 MHz Evaluation Board (TQP7M9101-PCB2140)



**Notes:**

1. See Evaluation Board PCB Information section for PCB material and stack-up.
2. Component (R1) is a 39 pF capacitor and may be replaced with copper trace in the target application layout.
3. All components are of 0603 size unless otherwise specified.
4. Critical component placement locations:
  - Distance from U1 Pin 1 Pad (left edge) to C5 (right edge): 40 mils (4.5° at 2140 MHz)
  - Distance from U1 Pin 1 Pad (left edge) to C1 (right edge): 90 mils (10.0° at 2140 MHz)

## Bill of Material TQP7M9101-PCB2140

Reference Des.	Value	Description	Manuf.	Part Number
n/a	n/a	Printed Circuit Board	Qorvo	1100415
U1	n/a	Amplifier, SOT-89 pkg.	Qorvo	TQP7M9101
L1	15 nH	Inductor, 0805, 5%, Coilcraft CS Series	Coilcraft	0805CS-150XJLB
C1	1.8 pF	Cap., Chip, 0603, +/-0.1pF. 200V. NPO/COG	various	
C5	1.5 pF	Cap., Chip, 0603, +/-0.1pF. 200V. NPO/COG	various	
R1, C2	39 pF	Cap., Chip, 5%, 50V, NPO/COG	various	
C3	22 pF	Cap., Chip, 5%, 50V, NPO/COG	various	
C4	1.0 μF	Cap., Chip, 10%, 10V, X5R	various	
J3, J4	n/a	Solder Turret	various	

## Typical Performance TQP7M9101-PCB2140

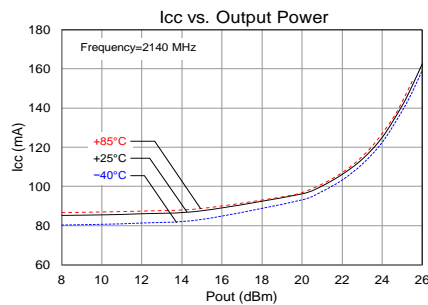
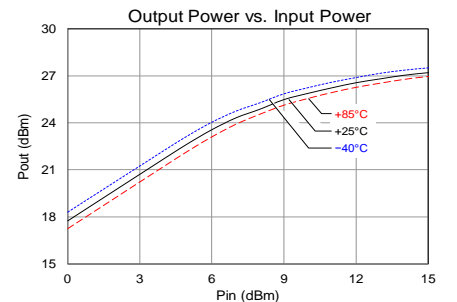
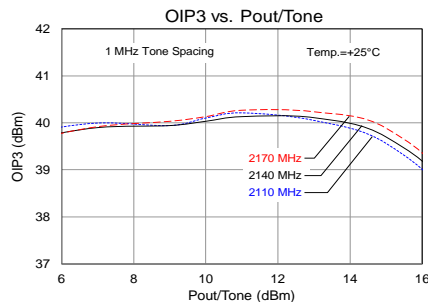
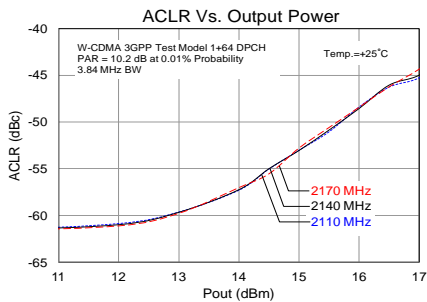
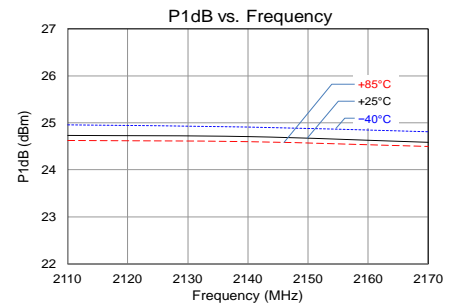
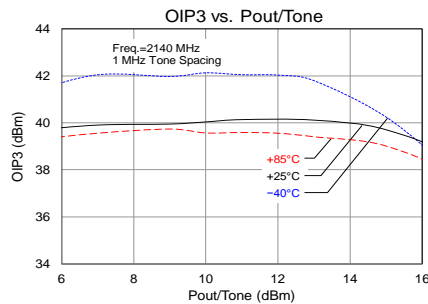
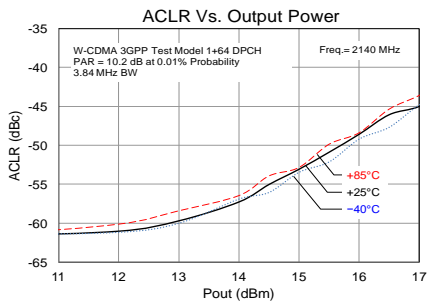
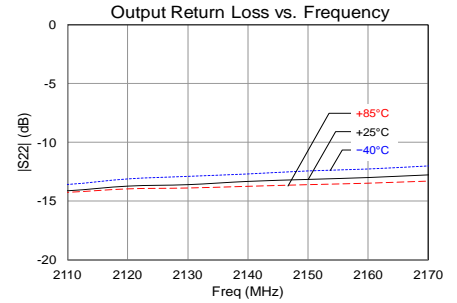
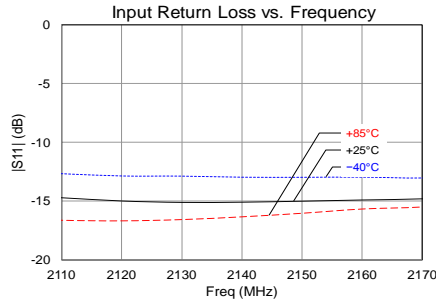
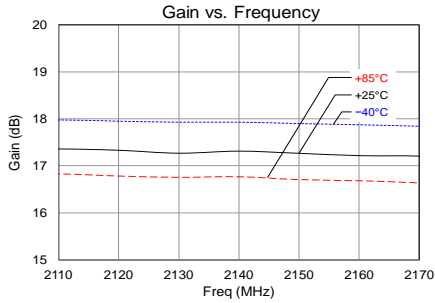
Parameter	Conditions <sup>(1)</sup>	Typical Value			Units
		2110	2140	2170	
Frequency		2110	2140	2170	MHz
Gain		17.6	17.5	17.4	dB
Input Return Loss		15	15	15	dB
Output Return Loss		14	13.5	13	dB
Output P1dB		+24.8	+24.8	+24.6	dBm
OIP3	Pout= +8 dBm/tone, Δf=1 MHz	+39.5	+39.5	+39.5	dBm
WCDMA Channel Power	-55 dBc ACLR, Note 2	+14.5	+14.5	+14.5	dBm
Noise Figure		4.0	3.9	4.1	dB

**Notes:**

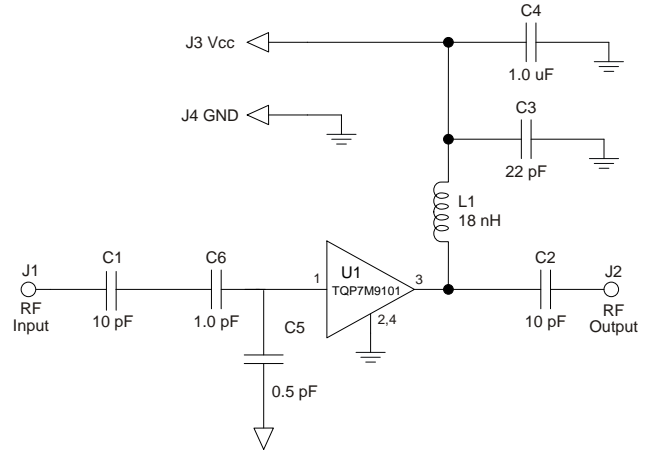
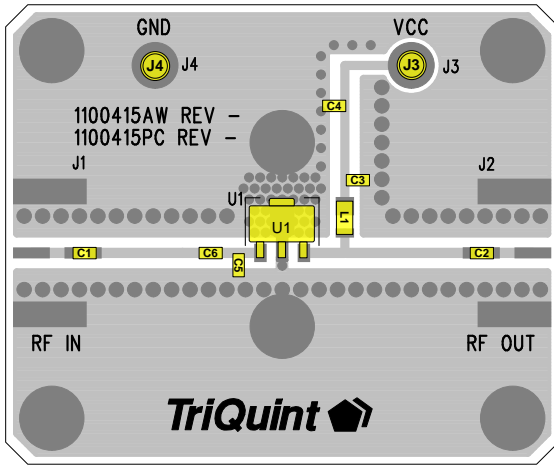
1. Test conditions unless otherwise noted: V<sub>CC</sub> = +5 V, I<sub>CO</sub> = 87 mA (typ.), Temp. = +25 °C
2. ACLR Test set-up: 3GPP WCDMA, TM1+64 DPCH, +5 MHz offset, PAR = 10.2 dB at 0.01% Prob

### Performance Plots – TQP7M9101-PCB2140

Test conditions unless otherwise noted:  $V_{CC} = +5\text{ V}$ ,  $I_{CQ} = 87\text{ mA}$  (typ.), Temp. =  $+25\text{ }^{\circ}\text{C}$



## 2.5 – 2.7 GHz Evaluation Board (TQP7M9101-PCB2600)



**Notes:**

1. See Evaluation Board PCB Information for material and stack up.
2. The recommended component values are dependent upon the frequency of operation.
3. All components are of 0603 size unless stated on the schematic.
4. Critical component placement locations:  
 Distance from U1 Pin 1 (left edge) to C5 (right edge): 80 mils  
 Distance from U1 Pin 1 (left edge) to C6 (right edge): 120 mils

## Bill of Material TQP7M9101-PCB2600

Reference Des.	Value	Description	Manuf.	Part Number
n/a	n/a	Printed Circuit Board	Qorvo	1100415
U1	n/a	0.25 W High Linearity Amplifier	Qorvo	TQP7M9101
C6	1.0 pF	CAP, 0603, +/-0.1pF. 200V. NPO/COG	various	
C5	0.5 pF	CAP, 0603, +/-0.1pF. 200V. NPO/COG	various	
C1 , C2	10 pF	Cap., Chip, 0603, +/-5%. 50V NPO/COG	various	
C3	22pF	Cap., Chip, 0603, +/-5%. 50V NPO/COG	various	
C4	1.0 μF	CAP, 0603, 10%, X5R , 10V	various	
L1	18 nH	Inductor, 0805, 5%, Coilcraft CS series	Coilcraft	0805CS-180XJLB
J3, J4	n/a	Solder Turret	various	

## Typical Performance TQP7M9101-PCB2600

Parameter	Conditions <sup>(1)</sup>	Typical Value			Units
Frequency		2500	2600	2700	MHz
Gain		16.5	16.5	16.2	dB
Input Return Loss		9	10	10	dB
Output Return Loss		17	14	13	dB
Output P1dB		+25.1	+24.9	+25.0	dBm
OIP3	Pout= +8 dBm/tone, Δf=1 MHz	+40.2	+40.6	+41.3	dBm
WCDMA Channel Power	-50 dBc ACLR, Note 2	+14.3	+14.4	+14.3	dBm

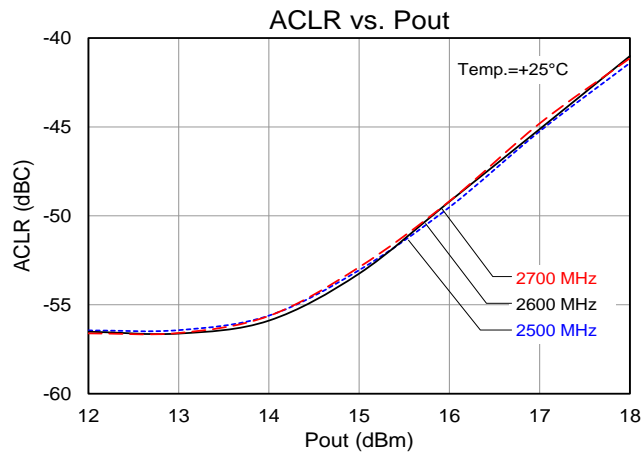
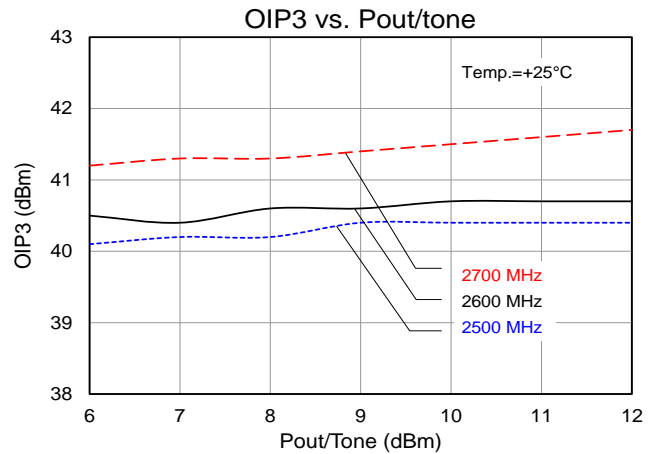
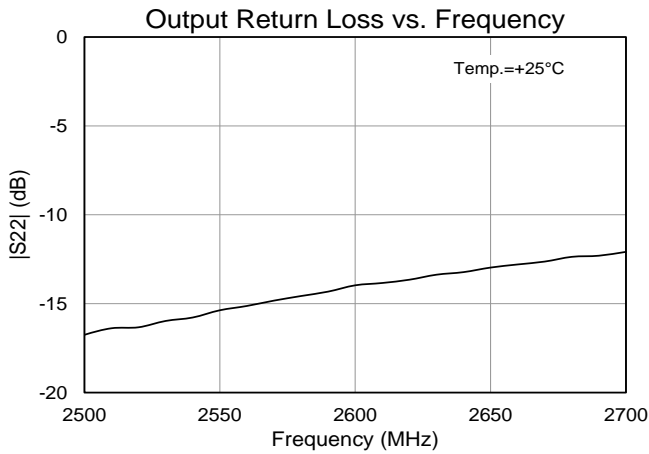
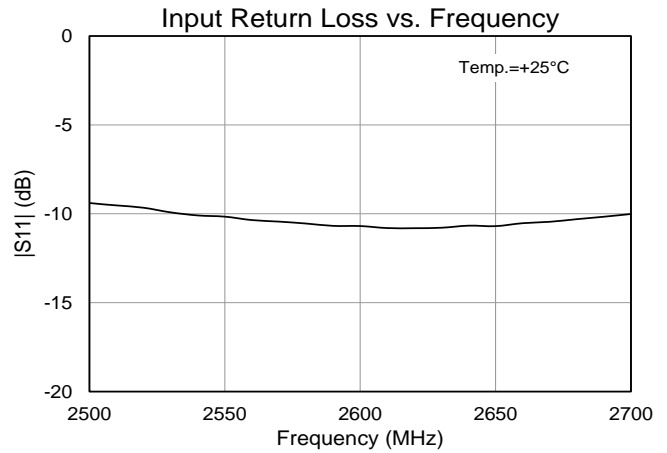
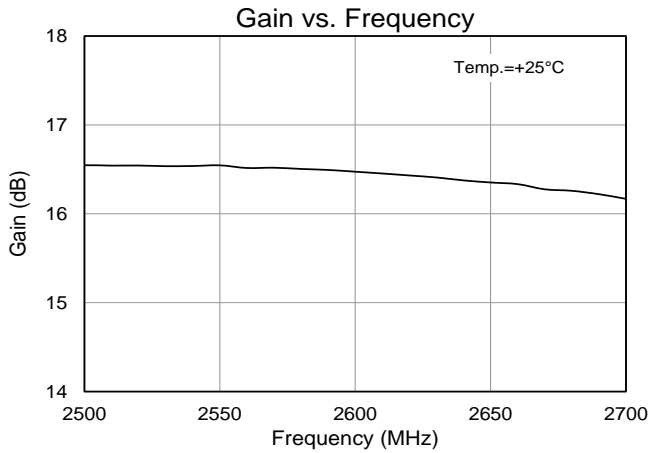
**Notes:**

1. Test conditions unless otherwise noted:  $V_{CC} = +5V$ ,  $I_{CO} = 87\text{ mA}$  (typ.), Temp. = +25 °C
2. ACLR Test set-up: 3GPP WCDMA, TM1+64 DPCH, +5 MHz offset, PAR = 10.2 dB at 0.01% Prob.

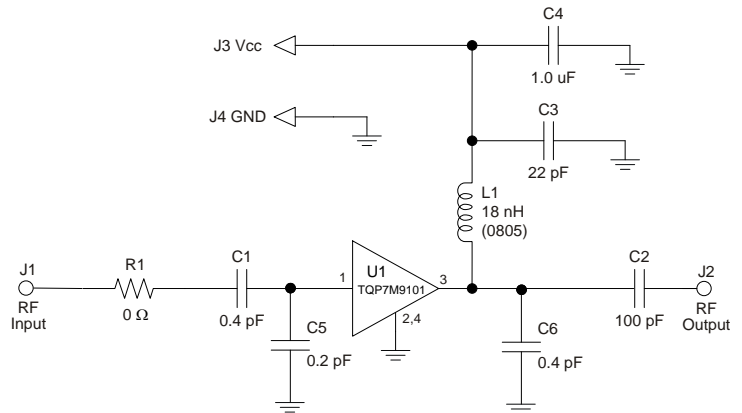
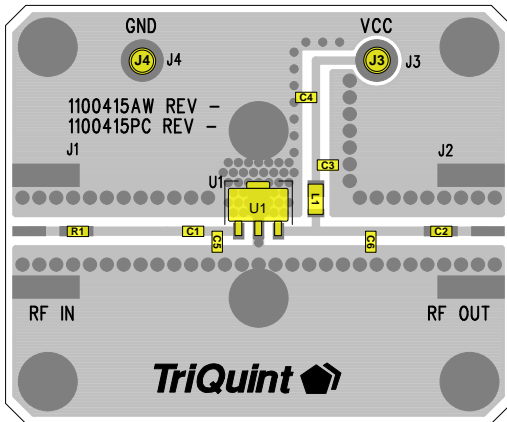


Performance Plots TQP7M9101-PCB2600

Test conditions unless otherwise noted:  $V_{CC} = +5\text{ V}$ ,  $I_{CQ} = 87\text{ mA}$  (typ.), Temp. =  $+25\text{ }^{\circ}\text{C}$



## 3400 – 3600 MHz Reference Design



**Notes:**

1. See Evaluation Board PCB Information for material and stack up.
2. Components shown on the silkscreen but not on the schematic are not used.
3. 0 Ω resistors (R1) may be replaced with copper trace in the target application layout.
4. The recommended component values are dependent upon the frequency of operation.
5. All components are of 0603 size unless stated on the schematic.
6. Critical component placement locations:
  - Distance from U1 Pin 1 (left edge) to C1 (right edge): 90 mils
  - Distance from U1 Pin 1 (left edge) to C5 (right edge): 30 mils
  - Distance from U1 Pin 3 (right edge) to C6 (left edge): 300 mils

## Bill of Material 3400 – 3600 MHz Reference Design

Reference Des.	Value	Description	Manuf.	Part Number
n/a	n/a	Printed Circuit Board	Qorvo	1100415
U1	n/a	0.25 W High Linearity Amplifier	Qorvo	TQP7M9101
R1	0 Ω	RES , 0603, 5PCT. 1/16W. CHIP	various	
C1 , C6	0.4 pF	CAP, 0603, ± 0.05 pF, 50V, ACCU-P	AVX	06035J0R4ABSTR
C5	0.2 pF	CAP, 0603, ± 0.05 pF, 50V, ACCU-P	AVX	06035J0R2ABSTR
C2	100 pF	Cap., Chip, 0603, +/-5%. 50V NPO/COG	various	
C3	22 pF	CAP, 0603, 5%, 50V, NPO/COG	various	
C4	1.0 μF	CAP, 0603, 10%, X5R , 10V	various	
L1	18 nH	Inductor, 0805, 5%, Coilcraft CS series	Coilcraft	0805CS-180XJLB

## Typical Performance 3400 – 3600 MHz Reference Design

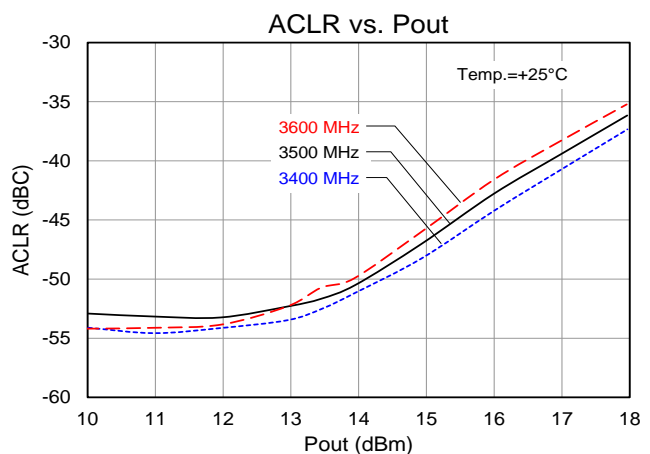
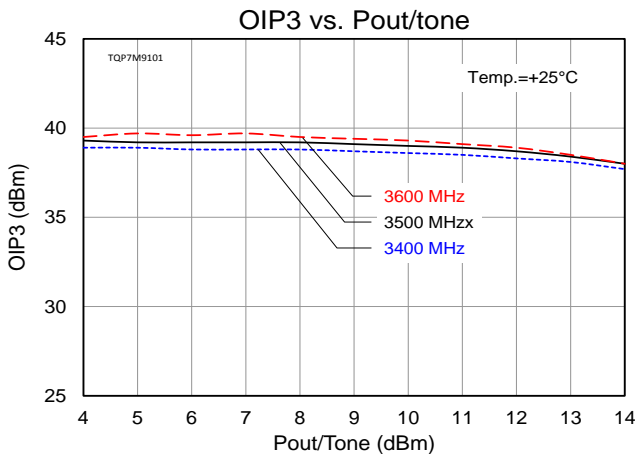
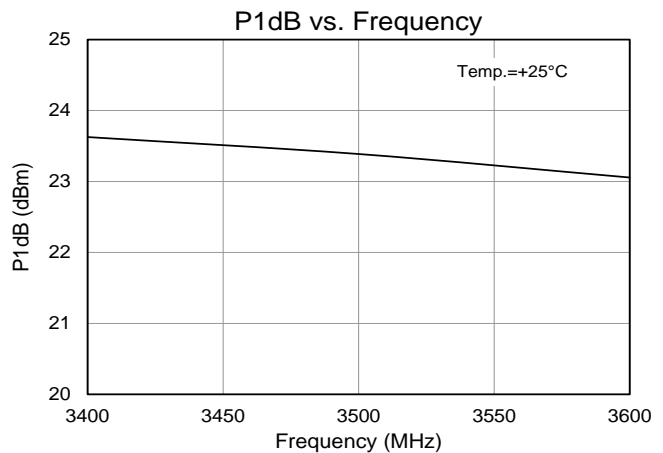
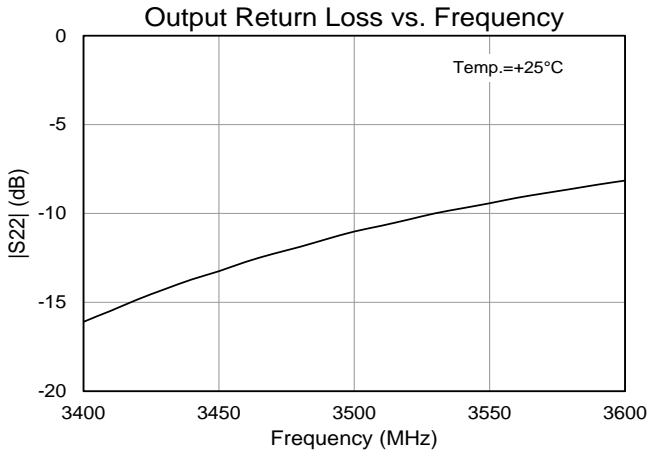
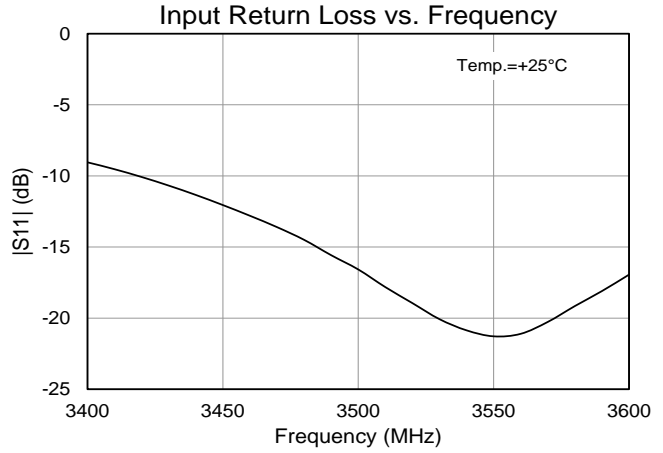
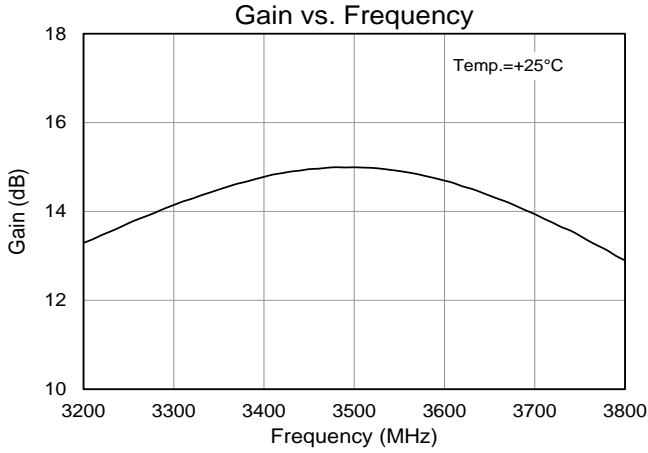
Parameter	Conditions <sup>(1)</sup>	Typical Value			Units
		3400	3500	3600	
Frequency		3400	3500	3600	MHz
Gain		14.8	15.0	14.7	dB
Input Return Loss		9	17	17	dB
Output Return Loss		16	11	7.5	dB
Output P1dB		+23.7	+23.4	+23.1	dBm
OIP3	Pout= +8 dBm/tone, Δf=1 MHz	+39.5	+39.4	+38.8	dBm
WCDMA Channel Power	-50 dBc ACLR, Note 2	+14.4	+14.1	+13.9	dBm

**Notes:**

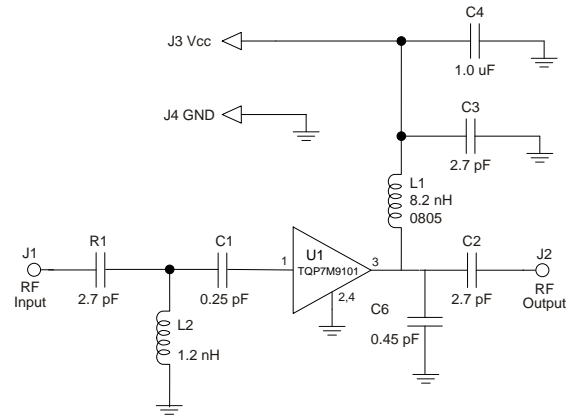
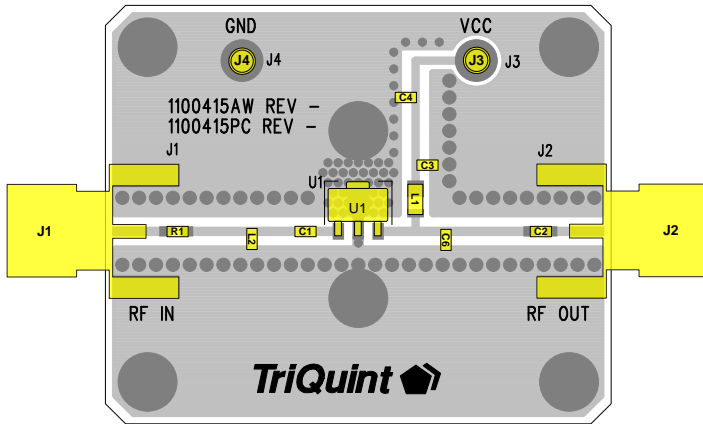
1. Test conditions unless otherwise noted: V<sub>CC</sub> = +5 V, I<sub>CC</sub> = 87 mA (typ.), Temp. = +25 °C
2. ACLR Test set-up: 3GPP WCDMA, TM1+64 DPCH, +5 MHz offset, PAR = 10.2 dB at 0.01% Prob

**Performance Plots 3400 – 3600 MHz Reference Design**

Test conditions unless otherwise noted:  $V_{CC} = +5\text{ V}$ ,  $I_{CQ} = 87\text{ mA}$  (typ.), Temp. =  $+25\text{ }^{\circ}\text{C}$



## 4.4 – 5.0 GHz Reference Design



**Notes:**

1. Components shown on the silkscreen but not on the schematic are not used.
2. 0 Ω resistor can be replaced with copper trace in the target application layout.
3. All components are of 0603 size unless stated on the schematic.
4. The recommended component values are dependent upon the frequency of operation.
5. Critical component placement locations:
  - Distance between U1 Pin 1 Pad (left edge) to C1 (right edge): 10 mils
  - Distance between U1 Pin 1 Pad (left edge) to L2 (right edge): 280 mils
  - Distance between U1 Pin 3 Pad (right edge) to C6 (left edge): 110 mils

## Bill of Material 4.4 – 5.0 GHz Reference Design

Reference Des.	Value	Description	Manuf.	Part Number
n/a	n/a	Printed Circuit Board	Qorvo	
U1	n/a	0.25 W High Linearity Amplifier	Qorvo	TQP7M9101
C1	0.25 pF	CAP, 0402, ± 0.02 pF, 50V, ACCU-P	AVX	04021JR25PBS
C6	0.45 pF	CAP, 0603, ± 0.02 pF, 50V, ACCU-P	AVX	06035JR45PBS
L2	1.2 nH	Inductor, 0603, chip	various	
C2, C3, R1	2.7 pF	CAP, 0603, ± 0.1 pF, 50V, NPO/COG	various	
C4	1.0 μF	CAP, 0603, 10%, X5R, 10V	various	
L1	8.2 nH	Inductor, 0805, 5%, Coilcraft CS series	Coilcraft	0805CS-8N2XJLB

## Typical Performance 4.4 – 5.0 GHz Reference Design

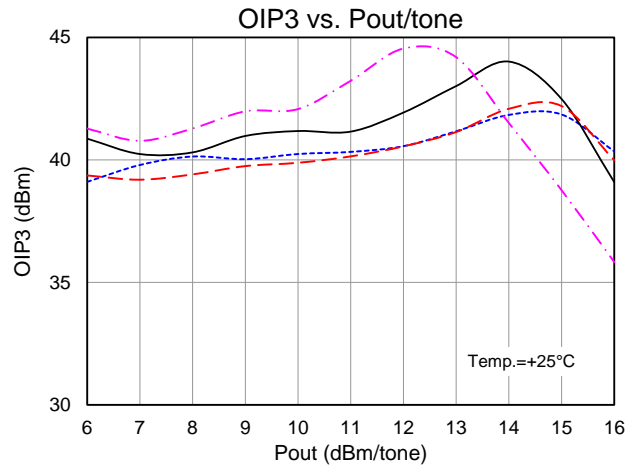
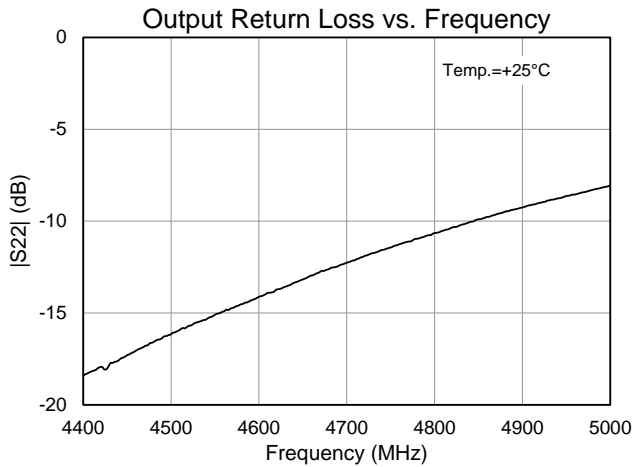
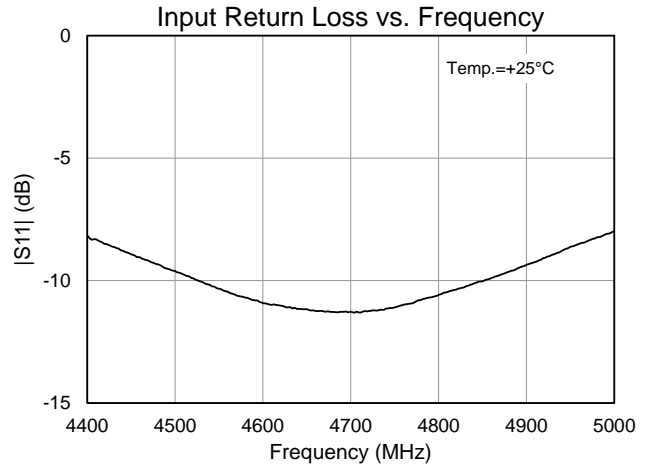
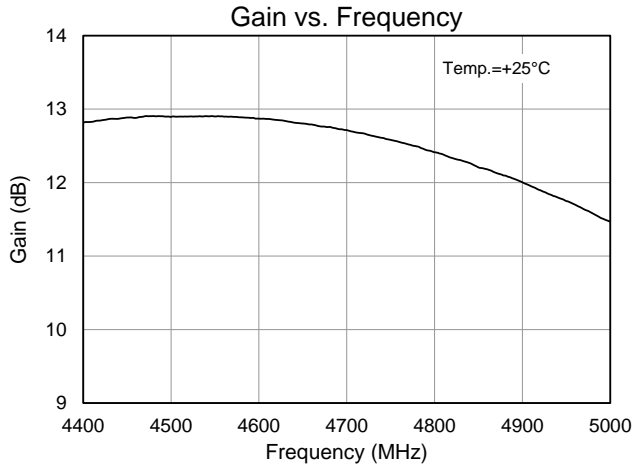
Parameter	Conditions <sup>(1)</sup>	Typical Value				Units
		4400	4600	4800	5000	
Frequency		4400	4600	4800	5000	MHz
Gain		12.8	12.9	12.4	11.5	dB
Input Return Loss		8.3	10.9	10.6	8.0	dB
Output Return Loss		18	14	11	8.1	dB
Output P1dB		+23.9	+23.5	+23.9	+23.1	dBm
Output IP3	Pout= +8 dBm/tone, Δf= 1 MHz	+40.1	+40.3	+39.4	+41.3	dBm
Quiescent Collector Current, I <sub>CC</sub>		86				mA

**Notes:**

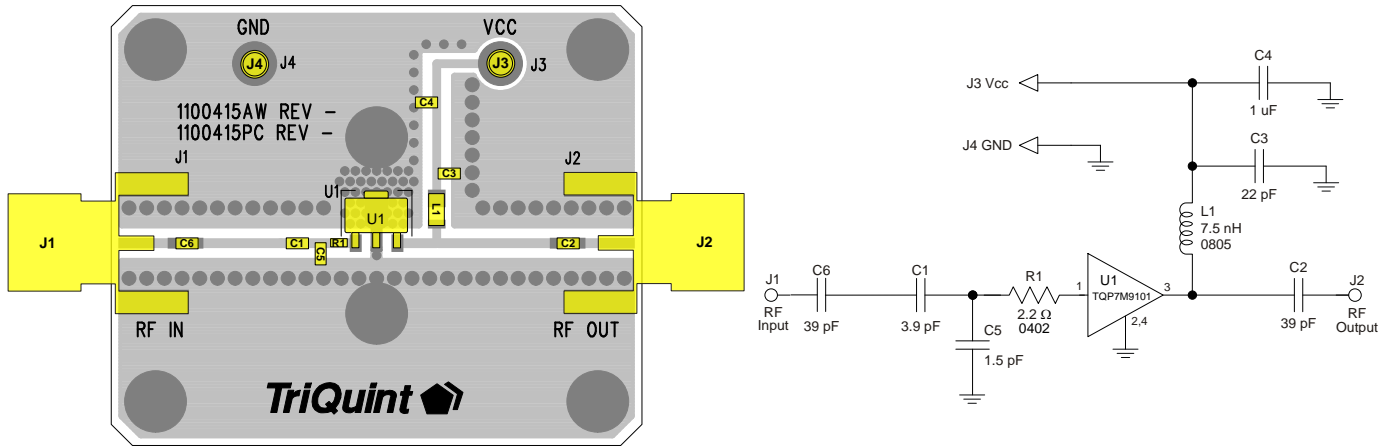
1. Test Conditions: V<sub>CC</sub>=+5V, Temp.=+25 °C, 50 Ω System

Performance Plots 4.4 – 5.0 GHz Reference Design

Test conditions unless otherwise noted:  $V_{CC} = +5\text{ V}$ ,  $I_{CQ} = 87\text{ mA}$  (typ.), Temp. =  $+25\text{ }^{\circ}\text{C}$



1800 – 2200 MHz Reference Design Optimized for OIP3



Notes:

- 6. All components are of 0603 size unless stated on the schematic.
- 7. The recommended component values are dependent upon the frequency of operation.
- 8. Critical component placement locations:
  - Distance between U1 Pin 1 Pad to R1 (right edge): 10 mil
  - Distance between U1 Pin 1 Pad to C5 (right edge): 45 mil
  - Distance between U1 Pin 3 Pad to C1 (right edge): 90 mil

Bill of Material 1800 – 2200 MHz Reference Design

Reference Des.	Value	Description	Manuf.	Part Number
n/a	n/a	Printed Circuit Board	Qorvo	
U1	n/a	0.25 W High Linearity Amplifier	Qorvo	TQP7M9101
C1	3.9 pF	CAP, 0603, +/-0.1pF. 200V. NPO/COG	various	
C5	1.5 pF	CAP, 0603, +/-0.1pF. 200V. NPO/COG	various	
C2, C6	39 pF	Cap., Chip, 0603, +/-5%. 50V NPO/COG	various	
C3	22 pF	Cap., Chip, 0603, +/-5%. 50V NPO/COG	various	
R1	2.2 Ω	Res., Chip, 0603, +/-1%, 1/10W	various	
C4	1.0 μF	CAP, 0603, 10%, X5R , 10V	various	
L1	7.5 nH	Inductor, 0805, 5%, Coilcraft CS series	Coilcraft	0805CS-7N5XJLB

Typical Performance 1800 – 2200 MHz Reference Design

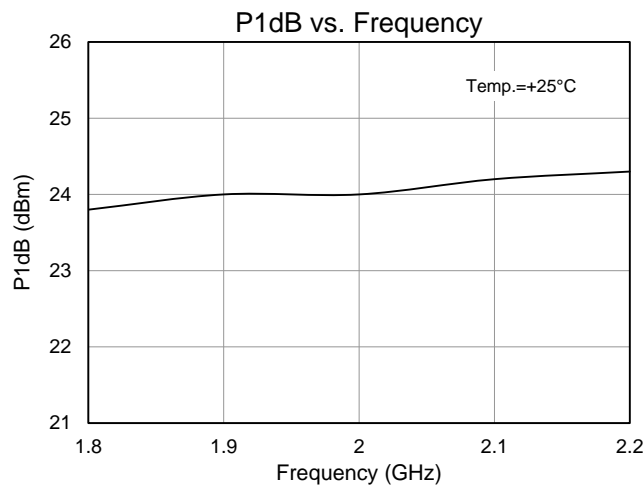
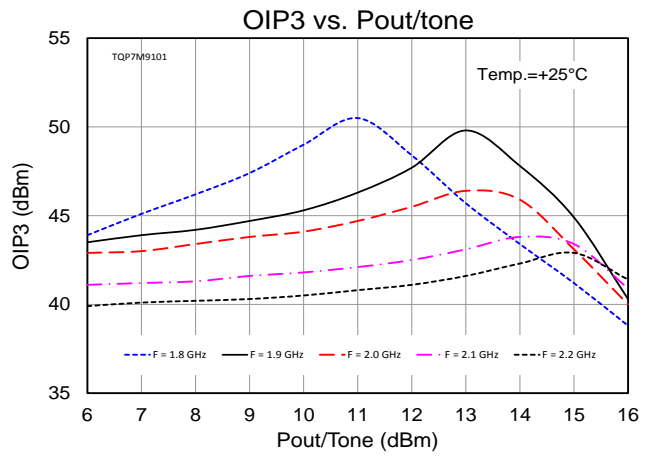
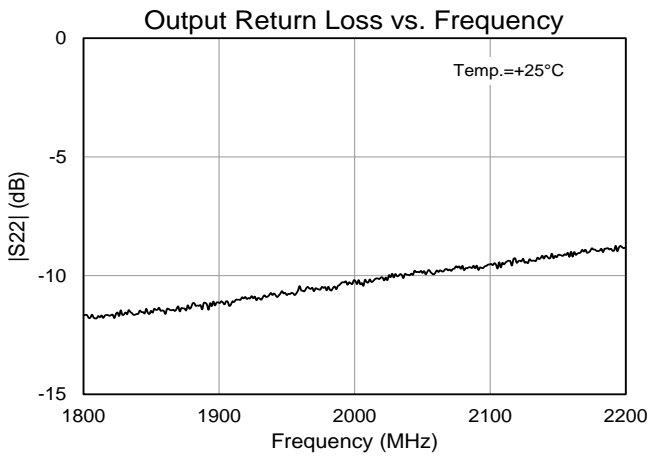
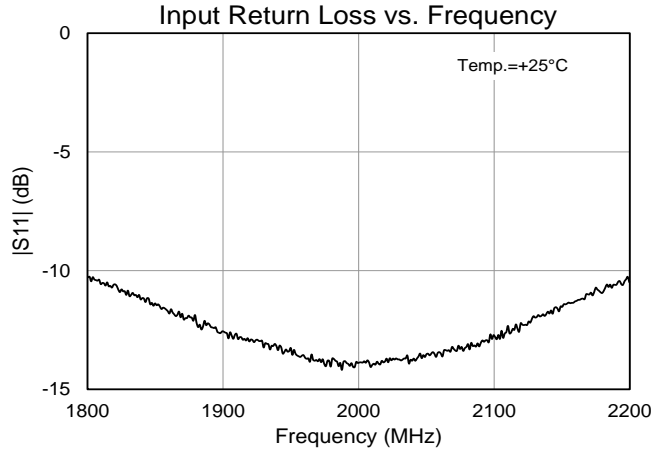
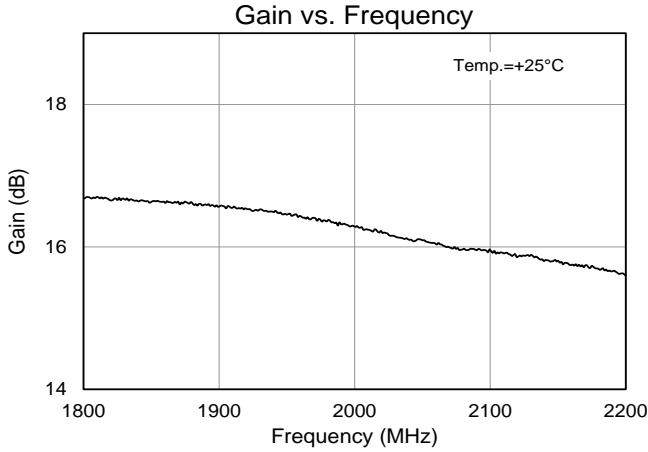
Parameter	Conditions	Typical Value					Units
		1800	1900	2000	2100	2200	
Frequency		1800	1900	2000	2100	2200	MHz
Gain		16.7	16.6	16.3	15.9	15.6	dB
Input Return Loss		10	12	13	12	10	dB
Output Return Loss		11	11	10	9.5	8.5	dB
Output P1dB		+23.8	+24.0	+24.0	+24.2	+24.3	dBm
Output IP3	Pout= +14 dBm/tone, Δf= 1 MHz	+43.4	+47.8	+45.9	+43.8	+42.3	dBm
Quiescent Collector Current, I <sub>CQ</sub>		87					mA

Notes:

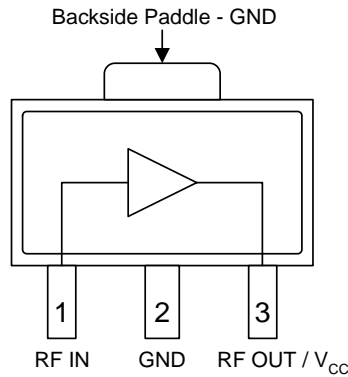
- 1. Test Conditions: V<sub>CC</sub>=+5 V, Temp.=+25 °C, 50 Ω System

Performance Plots 1800 – 2200 MHz Reference Design

Test conditions unless otherwise noted:  $V_{CC} = +5\text{ V}$ ,  $I_{CQ} = 87\text{ mA}$  (typ.), Temp. =  $+25\text{ }^{\circ}\text{C}$



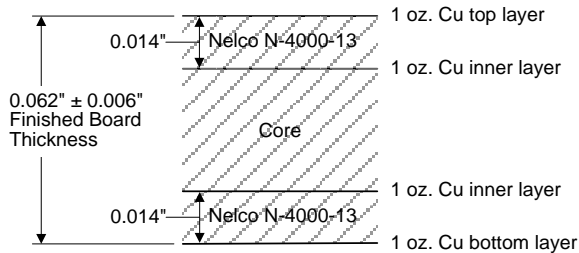
**Pin Configuration and Description**



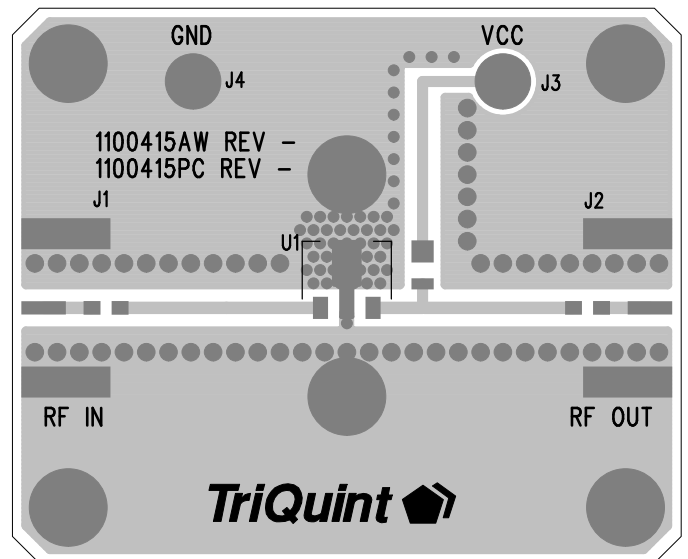
Pin No.	Label	Description
1	RF IN	RF Input. External DC Block required. Requires conjugate match for optimal performance.
2, Backside Paddle	GND	RF/DC ground. Use recommended via hole pattern to minimize inductance and thermal resistance. See PCB Mounting Pattern for suggested footprint.
3	RF OUT / V <sub>CC</sub>	RF output, matched to 50 ohms. External DC Block, RF choke and bias voltage required.

**Evaluation Board PCB Information**

**Qorvo PCB 1100415 Material and Stack-up**



50 ohm line dimensions: width = .031"  
spacing = .035".

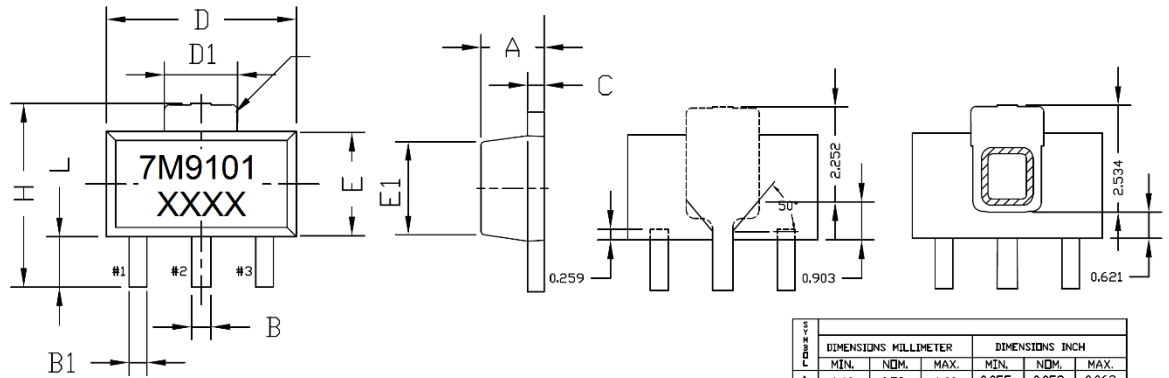




## Package Marking and Dimensions

### Package Marking

Product ID:  
7M9101  
Trace code:  
XXXX



Feature	DIMENSIONS MILLIMETER			DIMENSIONS INCH		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	1.40	1.50	1.60	0.055	0.059	0.063
B	0.42	0.49	0.56	0.017	0.019	0.022
B1	0.36	0.42	0.44	0.014	0.016	0.019
C	0.35	0.40	0.43	0.014	0.016	0.017
D	4.39	4.50	4.60	0.173	0.177	0.181
D1	1.40	1.62	1.83	0.055	0.062	0.072
E	2.29	2.44	2.60	0.090	0.098	0.102
E1	1.77	2.03	2.29	0.070	0.074	0.090
e	1.50 BSC			0.059 BSC		
e1	3.00 BSC			0.118 BSC		
H	3.84	4.04	4.25	0.151	0.155	0.167
L	0.74	0.97	1.20	0.029	0.041	0.047

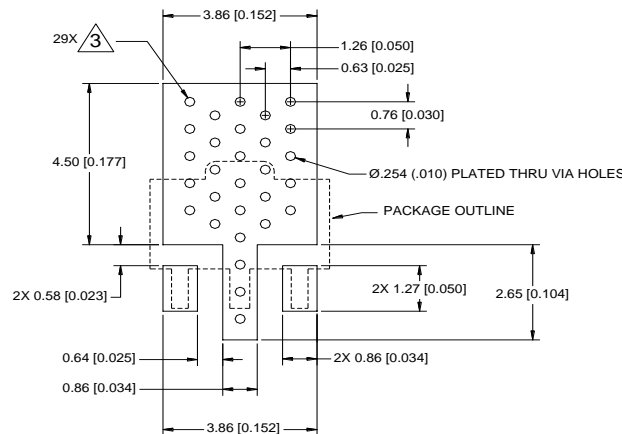
**NOTES :**

1. DIMENSIONING & TOLERANCING PER ANSI.Y14.5M-1982
2. CONTROLLING DIMENSION : MILLIMETER CONVERTED INCH ARE NOT NECESSARILY EXACT.
3. DIMENSION B1, 2 PLACES.

**Notes:**

1. The terminal #1 identifier and terminal numbering conform to JESD 95-1 SPP-012
2. Trace code up to 4 characters to be assigned by sub-contractor

## PCB Mounting Pattern



**Notes:**

1. All dimensions are in millimeters [inches]. Angles are in degrees.
2. Use 1 oz. copper minimum for top and bottom layer metal.
3. Via holes are required under the backside paddle of this device for proper RF/DC grounding and thermal conductivity.
4. Do not remove or minimize via hole structure in the PCB. Thermal and RF grounding is critical.
5. We recommend a 0.35mm (#80/.0135") diameter bit for drilling via holes and a final plated thru diameter of 0.25 mm (0.10").
6. Ensure good package backside paddle solder attach for reliable operation and best electrical performance.